Automotive NR1640
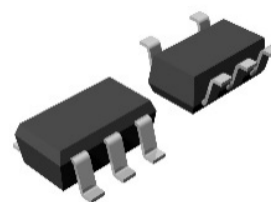# 200mA Ultra-low Noise Voltage Regulator

KEY SPECIFICATIONS

- AEC-Q100 grade 1 Under Evaluation
- Input Voltage Range (Maximum Rating)：
    2.7 V to 5.5 V (6.5 V)
- Operating Temperature Range： −40 °C to 125 °C
- Output Voltage Range： 2.5 V to 4.8 V
- Output Current： 200 mA
- Quiescent Current： Typ.350 μA
- Output Noise Voltage： Typ.6 μVrms (I_{OUT} = 100 mA)
- Ripple Rejection： Typ.80 dB (f = 1 kHz)
    Typ.80 dB (f = 100 kHz)
- Dropout Voltage： Typ.0.13 V
    (I_{OUT} = 200 mA, V_{SET} = 3.3 V)
- Thermal Shutdown Function： Typ.165 °C
- Slope of Output Voltage at Start-up：
    55 / 110 / 220 / 440 μs / V
    Selectable from 4 types
- Auto-discharge Function：Selectable by product name

APPLICATIONS

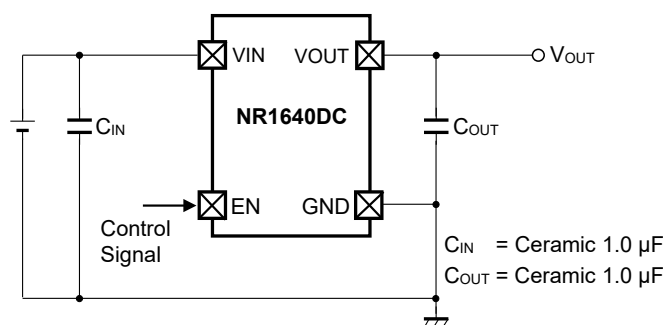- In-vehicle camera system
- High accuracy sensing systems

OVERVIEW

The NR1640 is a CMOS-based ultra-low noise, high PSRR voltage regulator featuring 200 mA output current and 5.5 V maximum input voltage.
With noise characteristics of 6 μVrms and high ripple rejection of 80 dB or more @100 kHz, high quality power can be supplied, ideal for high precision sensing systems where noise is an issue.
The slope of output voltage at startup can be selected from 4 types.
These options will meet the demand of suppression of inrush current and start-up slope requirement. In addition, the auto discharge function option will contribute to make the output shutdown fast to discharge output capacitance with internal discharge FET.
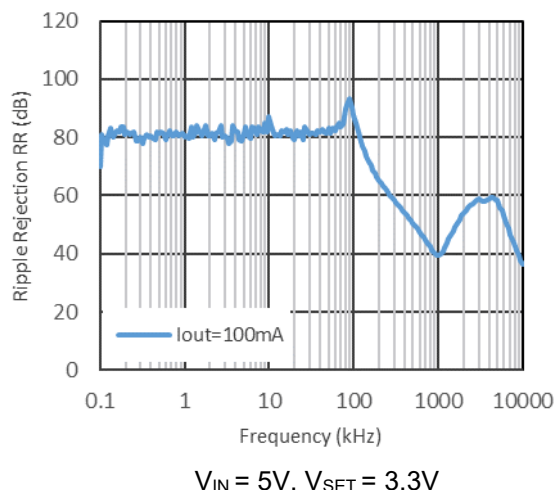
SOT-23-5-DC
2.9 × 2.8 × 1.1(㎜)

TYPICAL APPLICATIONS

C_{IN} = Ceramic 1.0 μF
C_{OUT} = Ceramic 1.0 μF

PSRR TYPICAL CHARACTERISTICS

Iout=100mA

V_{IN} = 5V, V_{SET} = 3.3V

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■ PRODUCT NAME INFORMATION

NR1640 aa   bbb   c   dd   e

Description of configuration

composition	Item	Description
aa	Package Code	Indicates the package. Refer to the order information.
bbb	Output Voltage	Set Output Voltage (V_{SET}) We have a lineup of major voltages in the range of 2.5 V (250) to 4.8 V (480).
c	Version	Indicates Slope of Output Voltage at Start-up and the selection of the auto discharge function.
dd	Packing	Refer to the packing specifications.
e	Grade	Indicates the quality grade.

Version

c	Slope of Output Voltage at Start-up	Auto-discharge Function
A	55 µs / V	Yes
B	110 µs / V	Yes
C	220 µs / V	Yes
D	440 µs / V	Yes
E	55 µs / V	No
F	110 µs / V	No
G	220 µs / V	No
H	440 µs / V	No

Grade

| e	Applications	Operating Temperature Range	Test Temperature
P	Chassis, Body control and In-vehicle	−40°C to 125°C	25°C, 125°C
Q	Powertrain and Safety driving related	−40°C to 125°C	-40°C, 25°C, 125°C

■ ORDER INFORMATION

PRODUCT NAME	PACKAGE	RoHS	HALOGEN-FREE	Plating Composition	MARKING	WEIGHT (mg)	Quantity per Reel (pcs)
NR1640DCbbbcE1e	SOT-23-5-DC	Yes	Yes	Sn	Reference	13.6	3000

Click here for details.
Note: Contact our sales representatives for other voltages.

■ **PIN DESCRIPTIONS**
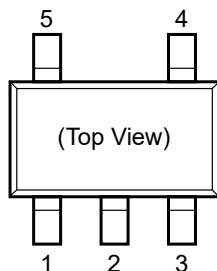

SOT-23-5-DC Pin Configuration

Pin No.	Pin Name	I/O	Description
1	VIN	Power	Power Supply Input Pin Connect the input capacitor between the VIN pin and GND.
2	GND	-	Ground Pin
3	EN	I	Enable Pin (Active-high) Can be set the active state with "High" input, the shutdown state with "Low". This pin is pulled down internally.
4	NC	-	No Connection It is recommended to make it open to prevent short circuit with adjacent pins during mounting.
5	VOUT	O	Output Pin Connect the output capacitor (C_{OUT}) between VOUT pin and GND.

Please refer to "*TYPICAL APPLICATION CIRCUIT*" or "*THEORY OF OPERATION*" for details.

■ **Internal Equivalent Circuit Diagram of Pin**
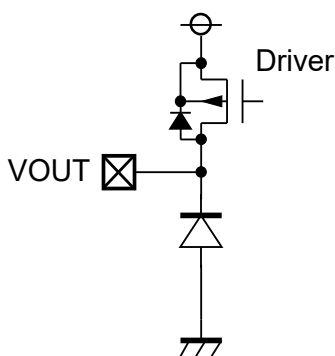
Internal equivalent circuit diagram of VOUT pin

Internal equivalent circuit diagram of EN pin

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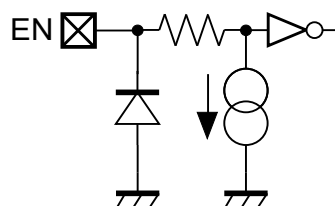
■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Ratings	Unit
Input Voltage	V_{IN}	−0.3 to 6.5	V
EN Pin Input Voltage	V_{EN}	−0.3 to 6.5	V
Output Voltage	V_{OUT}	−0.3 to V_{IN} + 0.3	V
Junction Temperature Range [*1]	T_j	−40 to 150	°C
Storage Temperature Range	T_{stg}	−55 to 150	°C

ABSOLUTE MAXIMUM RATINGS
Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause permanent damage and may degrade the lifetime and safety for both device and system using the device in the field. The functional operation at or over these absolute maximum ratings is not assured.

[*1] Calculate the power consumption of the IC from the operating conditions, and calculate the junction temperature with the thermal resistance.

Please refer to "*THERMAL CHARACTERISTICS*" for the thermal resistance under our measurement board conditions.

■ THERMAL CHARACTERISTIC

Item	Measurement Result
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

θja : Junction-to-Ambient Thermal Resistance
ψjt : Junction-to-Top Thermal Characterization Parameter

■ ELECTROSTATIC DISCHARGE(ESD) PROTECTION VOLTAGE

Item	Conditions	Protection Voltage
V_{HBM}	HBM : C = 100 pF, R = 1.5 kΩ	±2000 V
V_{CDM}	CDM	±1000 V

ELECTROSTATIC DISCHARGE RATINGS
The electrostatic discharge test is done based on JESD47. In the HBM method, ESD is applied using the power supply pin and GND pin as reference pins.

■ RECOMMENDED OPERATING CONDITIONS

Item	Symbol	Ratings	Unit
Input Voltage	V_{IN}	2.7 to 5.5	V
Operating Temperature Range	T_a	−40 to 125	°C
Output Current	I_{OUT}	0 to 200	mA

RECOMMENDED OPERATING CONDITIONS
All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

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■ ELECTRICAL CHARACTERISTICS

V_{IN} = V_{SET} + 1 V (Max. 5.5 V) , I_{OUT} = 1 mA, C_{IN} = 1.0 µF, C_{OUT} = 1.0 µF
Unless otherwise specified.
For parameter that do not describe the temperature condition, the MIN / MAX value under the condition of
−40 °C ≤ T_a ≤ 125 °C is described.

NR1640DCxxxxE1x

Parameter	Symbol	Conditions		MIN	TYP	MAX	Unit
Output Voltage	V_{OUT}	T_a = 25°C		×0.99	-	×1.01	V
		−40°C ≤ T_a ≤ 125°C		×0.985	-	×1.015	V
Quiescent Current	I_Q	V_{IN} = V_{SET} + 1 V (Max. 5.5 V) I_{OUT} = 0 mA		-	350	450	µA
Shutdown Current	I_{SD}	V_{IN} = 5.5 V, V_{EN} = 0 V		-	0.1	2.0	µA
Load Regulation	$\Delta V_{OUT}/\Delta I_{OUT}$	1 mA ≤ I_{OUT} ≤ 200 mA		-	-	20	mV
Line Regulation	$\Delta V_{OUT}/\Delta V_{IN}$	2.5 V ≤ V_{SET} ≤ 3.9 V, V_{SET} + 0.5 V ≤ V_{IN} ≤ 5.5 V I_{OUT} = 1 mA		-	-	0.1	%/V
		3.9 V < V_{SET} < 4.5 V, V_{SET} + 0.5 V ≤ V_{IN} ≤ 5.5 V I_{OUT} = 1 mA		-	-	0.15	
		4.5 V ≤ V_{SET} ≤ 4.8 V, V_{SET} + 0.3 V ≤ V_{IN} ≤ 5.5 V I_{OUT} = 1 mA					
Dropout Voltage	V_{DO}	I_{OUT} = 200 mA	2.5 V ≤ V_{SET} < 2.9 V	-	0.15	0.23	V
			2.9 V ≤ V_{SET} < 4 V	-	0.13	0.2	
			4 V ≤ V_{SET} ≤ 4.8 V	-	0.095	0.15	
Ripple Rejection	RR	f = 1 kHz		-	80	-	dB
		f = 100 kHz		-	80	-	dB
Output Noise Voltage	V_{NOISE}	f = 10 Hz to 100 kHz, I_{OUT} = 100 mA		-	6	-	µVrms
UVLO Release Voltage[*1]	$V_{UVLOREL}$	V_{IN} = Rising		-	-	2.7	V
UVLO Detection Voltage[*1]	$V_{UVLODET}$	V_{IN} = Falling		2.5	-	-	V
Output Current Limit	I_{LIM}	V_{IN} = V_{SET} + 1 V (Max. 5.5 V)		200	280	-	mA
Short Current Limit	I_{SC}	V_O = 0 V		40	75	100	mA
Limit Current at Start-up	$I_{LIMRISE}$	V_O = 0 V		100	140	180	mA
Slope of Output Voltage at Start-up	V_{OUTSS}	NR1640DCxxxA/E		37.5	55	72.5	µs/V
		NR1640DCxxxB/F		75	110	145	
		NR1640DCxxxC/G		150	220	290	
		NR1640DCxxxD/H		300	440	580	
EN Pin High Input Voltage	V_{ENH}			1.0	-	-	V
EN Pin Low Input Voltage	V_{ENL}			0	-	0.4	V
EN Pin Current	I_{EN}	V_{IN} = V_{EN} = 5.5 V		0.05	0.37	0.6	µA
Discharge FET On-resistance (ver. A/B/C/D)	R_{ONDIS}	V_{IN} = 3.6 V, V_{EN} = 0 V, V_O = 0.1 V		-	15	30	Ω
Thermal shutdown detection temperature	T_{SDDET}	T_j = Rising		150	165	-	°C
Thermal shutdown release temperature	T_{SDREL}	T_j = Falling		125	135	-	°C

All test parameters listed in Electrical Characteristics are done under the following conditions, except for ripple removal and output noise voltage.

NR1640DCxxxxxxP T_j ≈ T_a = 25°C, 125°C
NR1640DCxxxxxxQ T_j ≈ T_a = -40°C, 25°C, 125°C

*1 Due to the circuit configuration, V_{UVLOF} ≥ V_{UVLOR} does not hold. The hysteresis is Typ.0.08 V

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■ **PRODUCT-SPECIFIC ELECTRICAL CHARACTERISTICS**

PRODUCT NAME	V_{OUT} (T_a = 25°C)			V_{OUT} (-40 ≤ T_a ≤ 125°C)		
	MIN	TYP	MAX	MIN	TYP	MAX
NR1640DC250xxxx	2.475	2.5	2.525	2.462	2.5	2.538
NR1640DC280xxxx	2.772	2.8	2.828	2.758	2.8	2.842
NR1640DC290xxxx	2.871	2.9	2.929	2.856	2.9	2.944
NR1640DC300xxxx	2.970	3.0	3.030	2.955	3.0	3.045
NR1640DC330xxxx	3.267	3.3	3.333	3.250	3.3	3.350
NR1640DC340xxxx	3.366	3.4	3.434	3.349	3.4	3.451
NR1640DC480xxxx	4.752	4.8	4.848	4.728	4.8	4.872

Above parameters are all tested under the following conditions:

NR1640DCxxxxxxP T_j ≈ T_a = 25°C, 125°C
NR1640DCxxxxxxQ T_j ≈ T_a = -40°C, 25°C, 125°C

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■ **TYPICAL APPLICATION CIRCUIT**
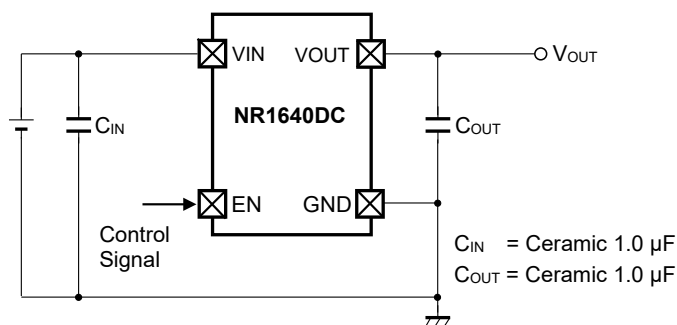
NR1640DC Typical Application Circuit

C_{IN} = Ceramic 1.0 µF
C_{OUT} = Ceramic 1.0 µF

Technical Notes Related to External Components

Ensure the VIN and GND lines are sufficiently robust. If their impedances are too high, noise pickup or unstable operation may result. Connect a 1.0 µF or more input capacitor (C_{IN}) between the VIN and GND pins with shortest-distance wiring.

It is recommended to use a ceramic capacitor of 6.3 V and more such as the X7R having small temperature dependence to ESR, ESL, and capacitance.

Phase compensation is provided to secure stable operation even when the load current is varied. For this purpose, use a ceramic capacitor of 1.0 µF or more with ESR (Equivalent Series Resistance) of up to 300 mΩ to connect an output capacitor (C_{OUT}) between the VOUT and GND pins with shortest-distance wiring. Besides, set for the output capacitor to ensure the following effective capacitance in consideration of the dependence of temperature, DC bias, and package size.

Set Output Voltage (V_{SET})	Effective Capacity
2.5 V ≤ V_{SET} ≤ 3.3 V	0.7 µF
3.3 V < V_{SET} ≤ 4.8 V	0.6 µF

In case of using an output capacitor of 1.0 µF or more, place a 1.0 µF ceramic capacitor as close as possible.
When using a capacitor with a large ESR such as a tantalum capacitor, select a component that satisfies the stability of the ESR. When using a capacitor with a large ESR such as a tantalum capacitor, select a component that satisfies the stability of the ESR. It is recommend using a low ESR capacitor that is sufficient for stable operation.

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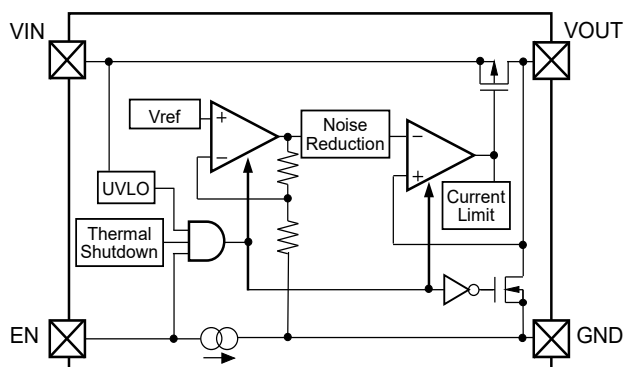
■ **BLOCK DIAGRAMS**

NR1640DCxxxA/B/C/D   Block Diagram
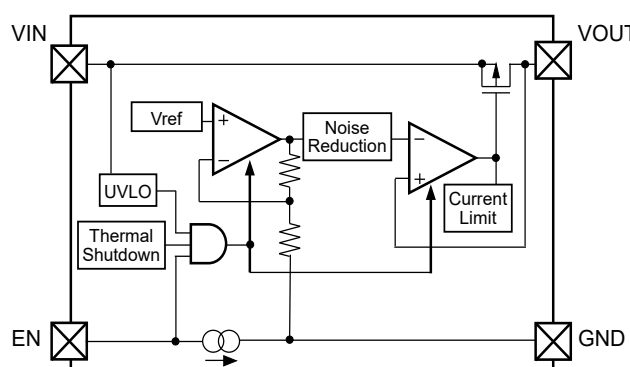
NR1640DCxxxE/F/G/H   Block Diagram

■ **THEORY OF OPERATION**

● **Enable Function**

Forcing above designated "High" voltage to EN pin, the NR1640 becomes active. Forcing below designated "Low" voltage to EN pin shuts down the NR1640. The EN pin is pulled down with a constant current of Typ.0.37 µA inside the IC. In shutdown condition, all functions are disabled except Auto Discharge function. (Option) With Auto-Discharge option, the MOSFET to discharge the output capacitor turns on and the output is pulled down to GND. Without Auto-Discharge option, the output becomes "Hi-Z". EN pin can accept input range voltage regardless of the input of VIN pin. If Enable function is not necessary, tie EN pin to VIN pin or other designated "High" voltage node at start-up.

● **Auto Discharge Function**

When turned off, the Vout voltage drops rapidly to near 0V by discharging the charge stored in the output capacitor through the MOSFET connected between the VOUT and GND pins. The auto discharge function is enabled when the EN pin = "low" or the thermal shutdown detection. This function is effective when the input voltage aboves the minimum operating voltage. On-resistance of MOSFET is Typ.15Ω.

● **Thermal Shutdown**

When the junction temperature exceeds the thermal shutdown detection temperature (Typ.165°C), this IC cuts off the output and suppresses the self-heating. When the junction temperature falls below the thermal shutdown release temperature (Typ.135°C), this IC will restart with the soft start operation.

● Soft-start / Inrush Current Limit

The soft start function is a function that makes the rise of the output voltage (V_{SET}) a fixed time (V_{SET} x V_{OUTSS}) by starting up the internal reference voltage generated inside the IC with the selected slope of output voltage at start-up (V_{OUTSS}) .
By this function, the output voltage at start-up rises up slowly and the inrush current at start-up can be suppressed. NR1640 builts in the Inrush current limit circuit. After the EN pin becomes "High", the inrush current which flows at charging the C_{OUT}, is limited at Typ.140 mA.
If an effective capacitance value of the connected C_{OUT} is larger than 0.14 x V_{OUTSS}, the charging current is limited. So, the output voltage rises more slowly than the selected slope of output voltage at start-up (V_{OUTSS}). If the load current (I_{LOAD}) is smaller than the charging current to the C_{OUT}, the output voltage ramp up time is determined by the inrush current limit value and C_{OUT} value. When the effective capacity value of C_{OUT} is about 0.14 x V_{OUTSS} or more, the output turning on time (t_{ON}) can be calculated from the following equation:

t_{ON} = t_D + C_{OUT} x V_{SET} / $I_{LIMRISE}$
t_D :   Delay Time at Start-up 35µs
V_{SET} :   Set Output Voltage
$I_{LIMRISE}$: Limit Current at Start-up   Typ.140mA

If the load current (I_{LOAD}) exists other than the charge current to C_{OUT} during start-up, the start-up time is extended.
The load current over $I_{LIMRISE}$ may interfere charging of C_{OUT} and the output does not rise up.
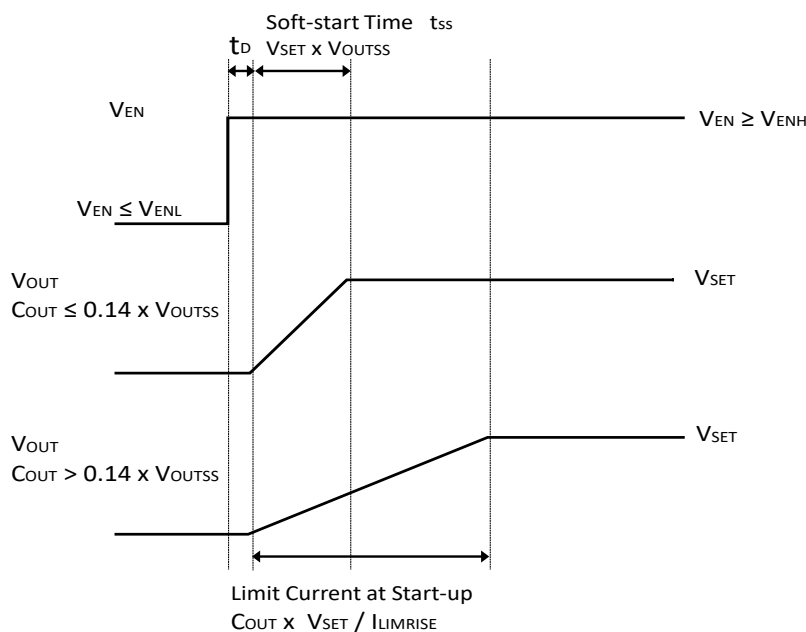
■THERMAL CHARACTERISTICS

Thermal characteristics depend on the mounting conditions.
The following measurement conditions are based on JEDEC STD. 51.

Measurement Conditions

Item	Measurement Conditions
Measurement status	Mounting on Board (Wind Velocity = 0 m/s)
Board material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board size	76.2 mm × 114.3 mm × 0.8 mm

Wiring rate	Outer Layer (First Layer):
	                      Less than 95% of 50 mm Square
	Inner Layers (Second and Third Layers):
	                      Approx. 100% of 50 mm Square
	Outer Layer (Fourth Layer):
	                      Approx. 100% of 50 mm Square

Through hole	φ 0.3 mm ×7 pcs

Measurement Result

Item	Measurement Result
Thermal Resistance (θja)	θja = 150°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 51°C/W

θja : Junction-to-Ambient Thermal Resistance

ψjt : Junction-to-Top Thermal Characterization Parameter
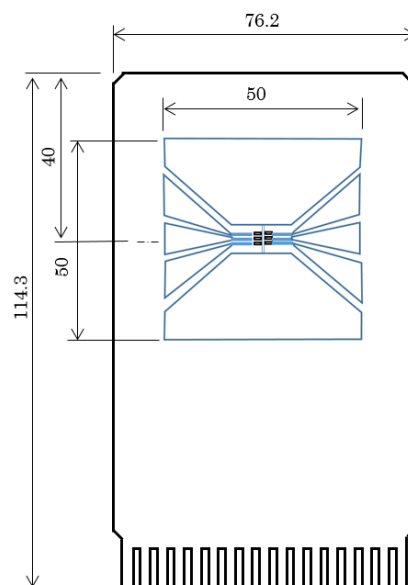
Measurement Board Pattern

■CALCULATION METHOD OF JUNCTION TEMPERATURE

The junction temperature (T_j) can be calculated from the following formula.

$T_j = T_a + \theta ja \times P$

$T_j = Tc \text{ (top)} + \psi jt \times P$

T_a: Ambient temperature

Tc (top) : Package mark side center temperature

P (Power consumption under user's conditions) : $(V_{IN} - V_{OUT}) \times I_{OUT}$

■ **MARKING SPECIFICATION**

①②③   : Product Code (Abbreviation)
④⑤   : Lot Number ・・・ Alphanumeric Serial Number

5		4
	①②③④⑤	
1	2	3
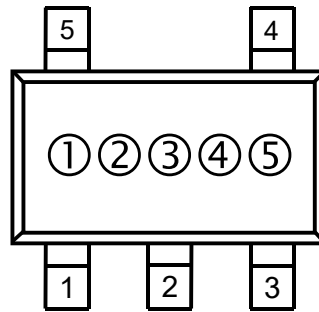
SOT-23-5-DC Marking

NOTICE
There can be variation in the marking when different AOI (Automated Optical Inspection) equipment is used. In the case of recognizing the marking characteristic with AOI, please contact our sales or distributor before attempting to use AOI.

■ ORDER INFORMATION（ALL）

PRODUCT NAME	PACKAGE	RoHS	HALOGEN-FREE	Plating Composition	MARKING	WEIGHT (mg)	Quantity per Reel (pcs)
NR1640DC250AE1e					A00		
NR1640DC280AE1e					A01		
NR1640DC290AE1e					A06		
NR1640DC300AE1e					A02		
NR1640DC330AE1e					A03		
NR1640DC340AE1e					A04		
NR1640DC480AE1e					A05		
NR1640DC250BE1e					B00		
NR1640DC280BE1e					B01		
NR1640DC290BE1e					B06		
NR1640DC300BE1e					B02		
NR1640DC330BE1e					B03		
NR1640DC340BE1e					B04		
NR1640DC480BE1e					B05		
NR1640DC250CE1e					C00		
NR1640DC280CE1e					C01		
NR1640DC290CE1e					C06		
NR1640DC300CE1e					C02		
NR1640DC330CE1e					C03		
NR1640DC340CE1e					C04		
NR1640DC480CE1e	SOT-23-5-DC	Yes	Yes	Sn	C05	13.6	3000
NR1640DC250DE1e					D00		
NR1640DC280DE1e					D01		
NR1640DC290DE1e					D06		
NR1640DC300DE1e					D02		
NR1640DC330DE1e					D03		
NR1640DC340DE1e					D04		
NR1640DC480DE1e					D05		
NR1640DC250EE1e					E00		
NR1640DC280EE1e					E01		
NR1640DC290EE1e					E06		
NR1640DC300EE1e					E02		
NR1640DC330EE1e					E03		
NR1640DC340EE1e					E04		
NR1640DC480EE1e					E05		
NR1640DC250FE1e					F00		
NR1640DC280FE1e					F01		
NR1640DC290FE1e					F06		
NR1640DC300FE1e					F02		
NR1640DC330FE1e					F03		
NR1640DC340FE1e					F04		
NR1640DC480FE1e					F05		

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PRODUCT NAME	PACKAGE	RoHS	HALOGEN-FREE	Plating Composition	MARKING	WEIGHT (mg)	Quantity per Reel (pcs)
NR1640DC250GE1e	SOT-23-5-DC	Yes	Yes	Sn	G00	13.6	3000
NR1640DC280GE1e					G01		
NR1640DC290GE1e					G06		
NR1640DC300GE1e					G02		
NR1640DC330GE1e					G03		
NR1640DC340GE1e					G04		
NR1640DC480GE1e					G05		
NR1640DC250HE1e					H00		
NR1640DC280HE1e					H01		
NR1640DC290HE1e					H06		
NR1640DC300HE1e					H02		
NR1640DC330HE1e					H03		
NR1640DC340HE1e					H04		
NR1640DC480HE1e					H05		

■ APPLICATION NOTES

Phase Compensation

Phase compensation is provided to secure stable operation even when the load current is varied by utilizing capacity of the output ceramic capacitor and Equivalent Series Resistance (ESR). For this purpose, use a capacitor for Cout with the capacity of equal or more than 1.0 µF. Depending on the ESR, the output may oscillate, so evaluate carefully including the temperature characteristics and frequency characteristics. Connect a capacitor (CIN) of 1.0 µF or more between the VDD and GND pins, and keep the wiring as short as possible.

Thermal Shutdown Function

The thermal shutdown function prevents the IC from fuming and ignition but does not ensure the IC's reliability or keep the IC below the absolute maximum ratings.

The thermal shutdown function does not operate on the heat generated by other than the normal IC operation such as latch-up and overvoltage application.

The thermal shutdown function operates in a state over the absolute maximum ratings, therefore the thermal shutdown function should not be used for a system design.

Evaluation Board / PCB Layout
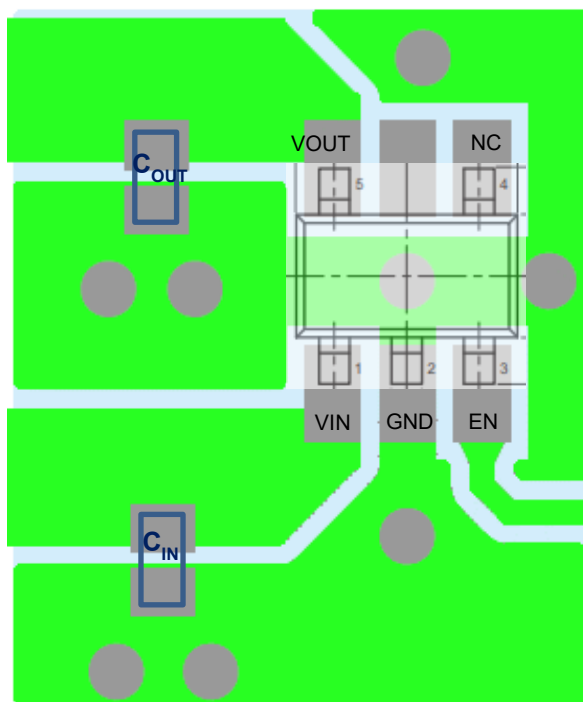
■ TYPICAL CHARACTERISTICS

Note: Typical Characteristics are intended to be used as reference data; they are not guaranteed.

1) Output Voltage vs Temperature
$V_{IN} = V_{SET} + 1$ V (Max = 5.5 V), $I_{OUT} = 1$ mA, $C_{IN} = C_{OUT} = 1.0$ μF
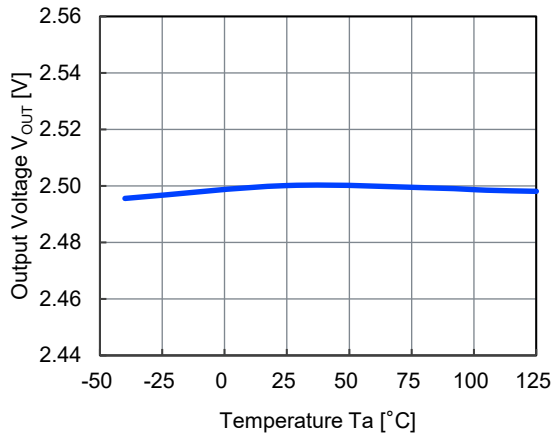
NR1640DC250x
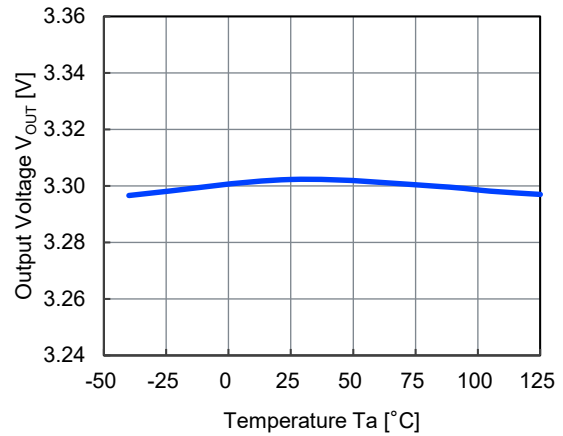
NR1640DC330x
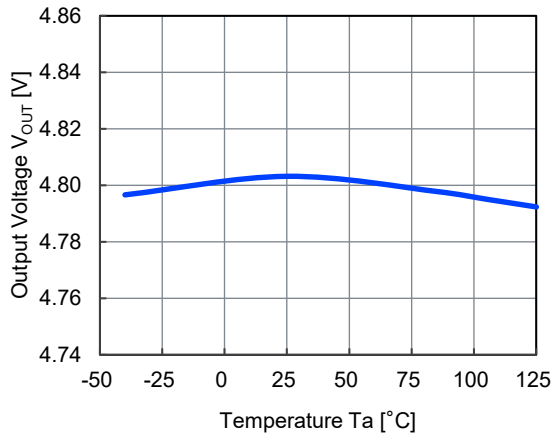
NR1640DC480x

2) Quiescent Current vs Temperature
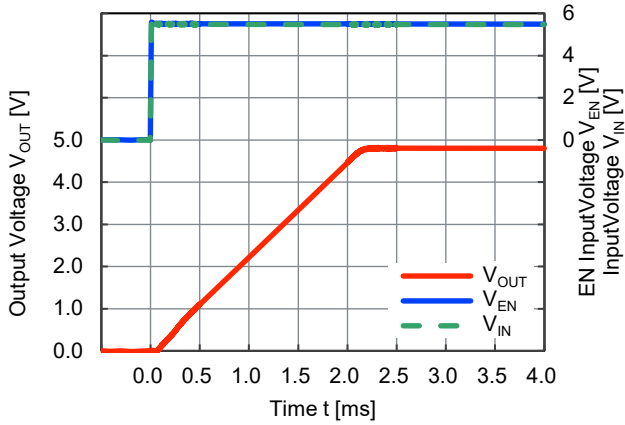$V_{IN} = V_{SET} + 1$ V (Max = 5.5 V), $C_{IN} = C_{OUT} = 1.0$ μF

NR1640DC250x

NR1640DC330x

Nisshinbo Micro Devices Inc.

NR1640DC480x

3) Dropout Voltage vs Output Current
$C_{IN} = C_{OUT} = 1.0$ μF
NR1640DC330x
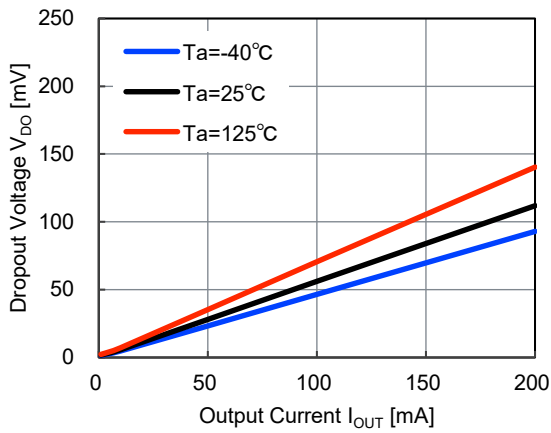
NR1640DC480x
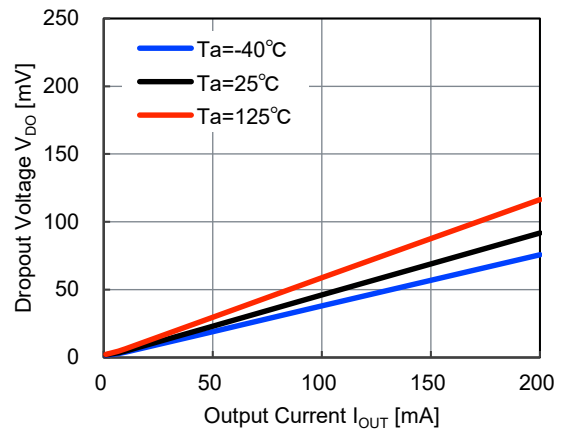
4) Dropout Voltage vs Set Output Voltage
$C_{IN} = C_{OUT} = 1.0$ μF, $T_a = 25$°C
NR1640DCxxxx
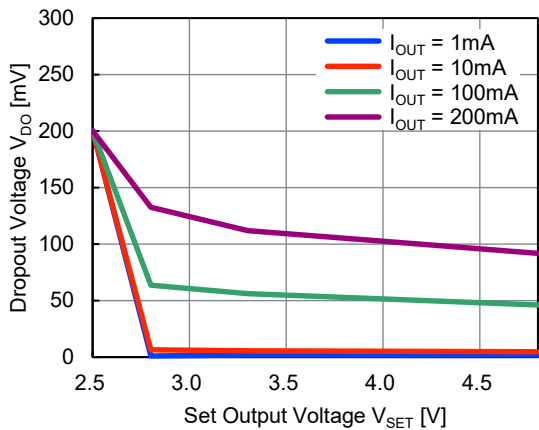
5) Output Voltage vs Output Current
$V_{IN} = V_{SET} + 1$ V (Max = 5.5 V), $C_{IN} = C_{OUT} = 1.0$ µF, Ta = 25°C
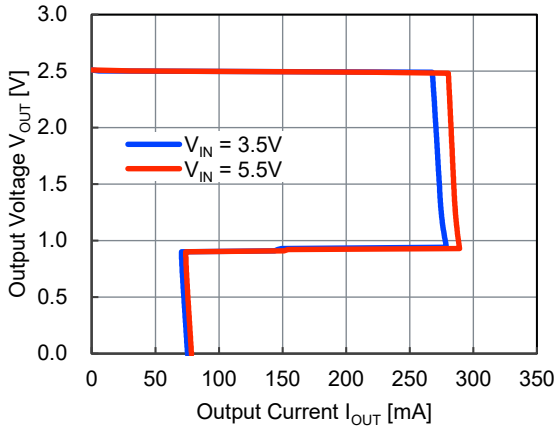
NR1640DC250x
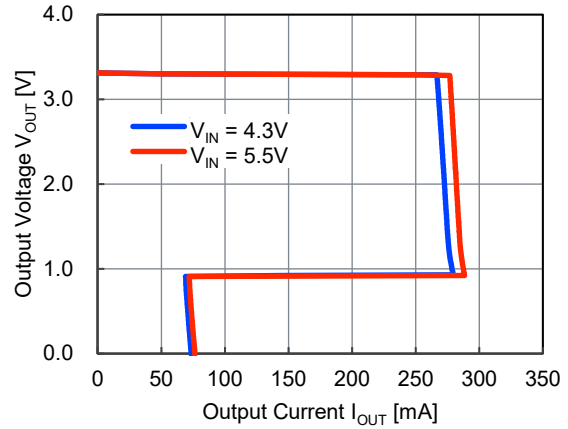
NR1640DC330x
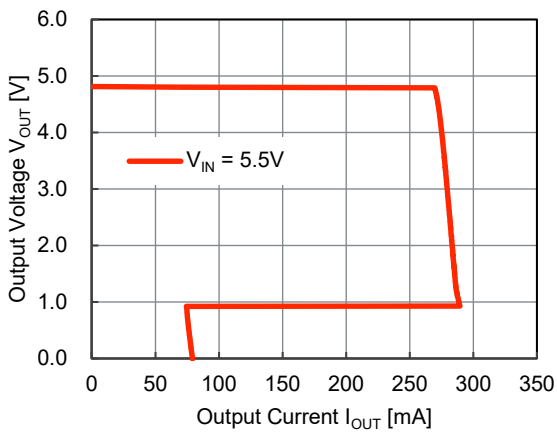
NR1640DC480x

6) Output Voltage vs Input Voltage
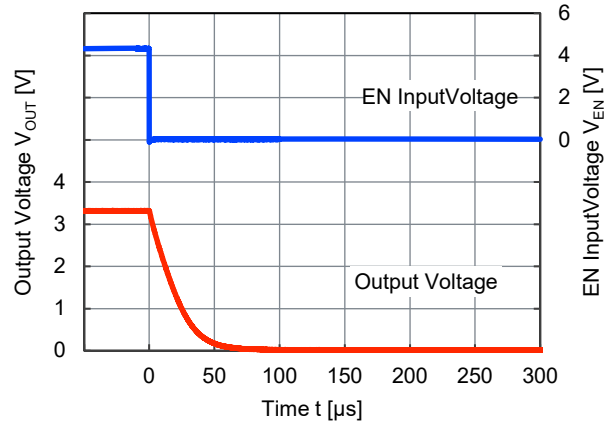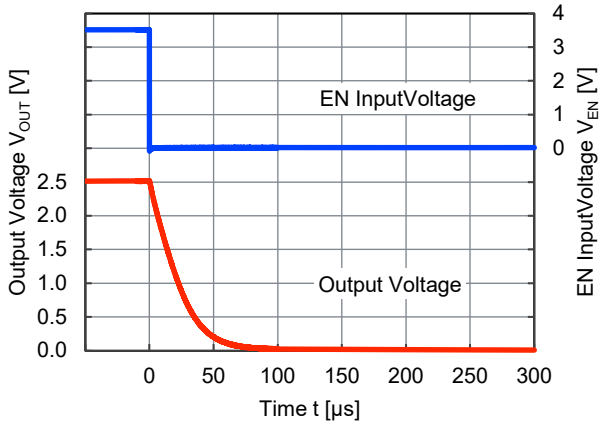$V_{IN} = V_{SET} + 1$ V (Max = 5.5 V) to 0 V, $C_{IN} = C_{OUT} = 1.0$ µF, $T_a = 25$°C

NR1640DC250x,（V_{IN}＝2.5V to 3.5V）
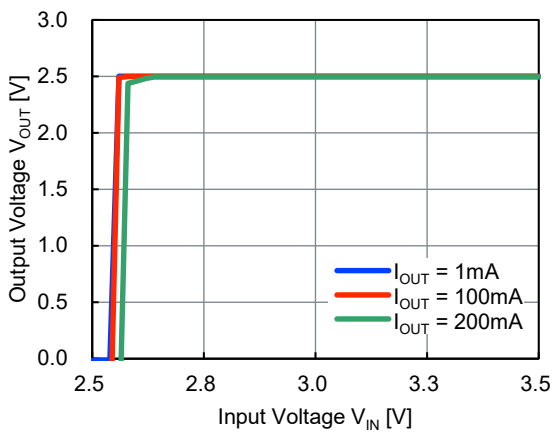
NR1640DC250x,（V_{IN}＝2.3V to 2.8V）
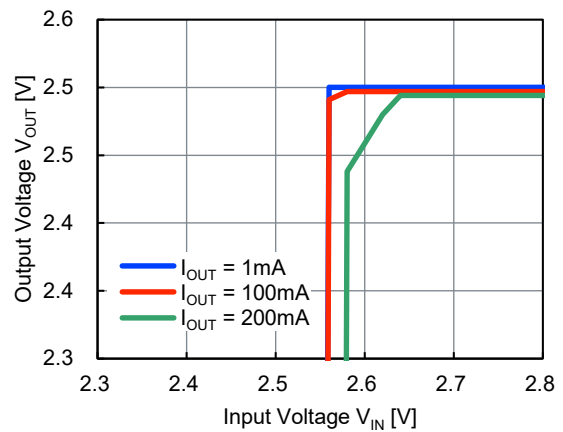
NR1640DC330x,（V_{IN}＝2.5V to 4.3V）
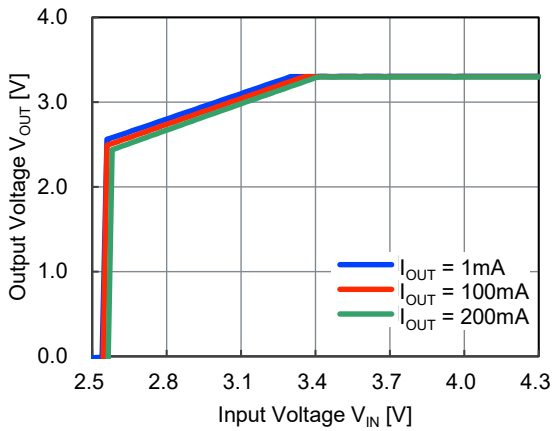
NR1640DC330x,（V_{IN}＝3.1V to 3.7V）
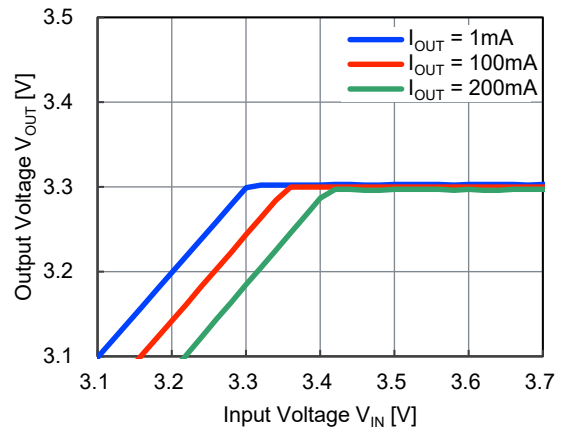
NR1640DC480x,（V_{IN}＝2.5V to 5.5V）
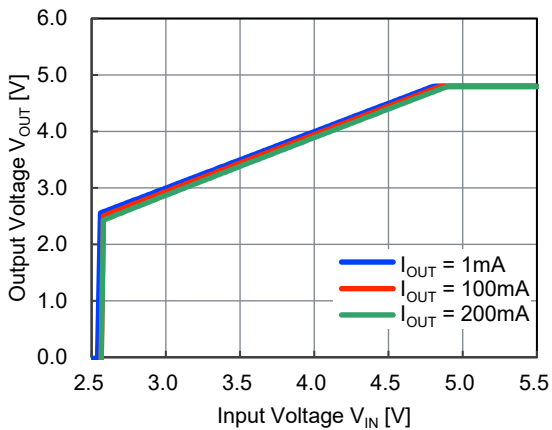
NR1640DC480x,（V_{IN}＝4.6V to 5.5V）
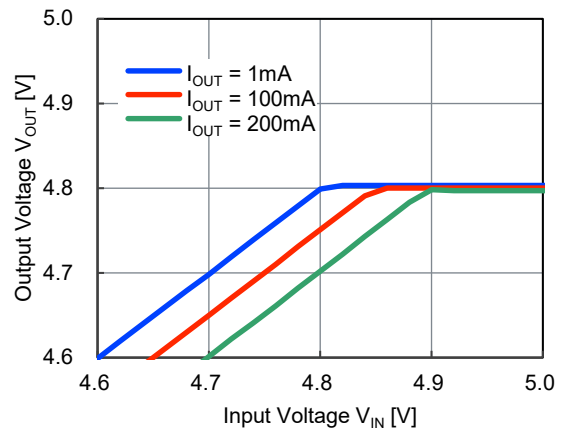
7) Quiescent Current　vs　Input Voltage
V_{IN} = V_{SET} + 1 V (Max = 5.5 V) to 0 V, C_{IN} = C_{OUT} = 1.0 μF, T_a = 25°C
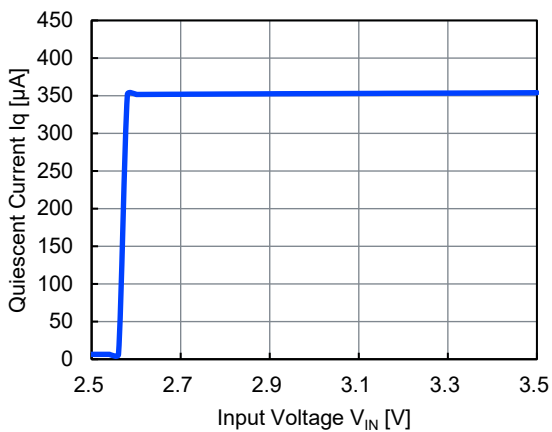
NR1640DC250x

NR1640DC330x
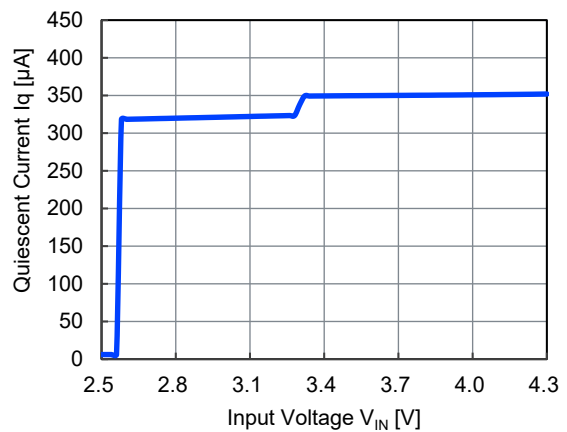
NR1640DC480x
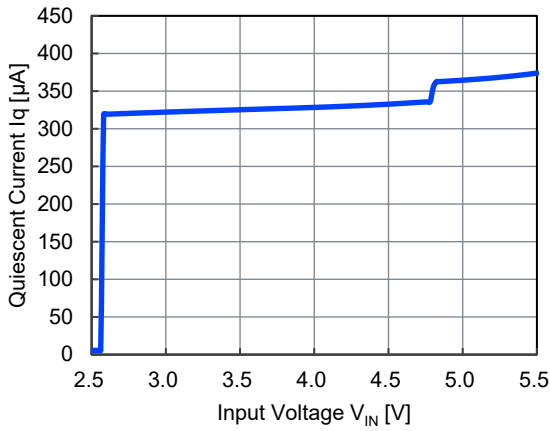
8) EN "High / Low" Input Voltage vs Temperature
$V_{IN} = V_{SET} + 1\ V$ (Max = 5.5 V), $C_{IN} = C_{OUT} = 1.0\ \mu F$
NR1640DCxxxx, EN = "High"
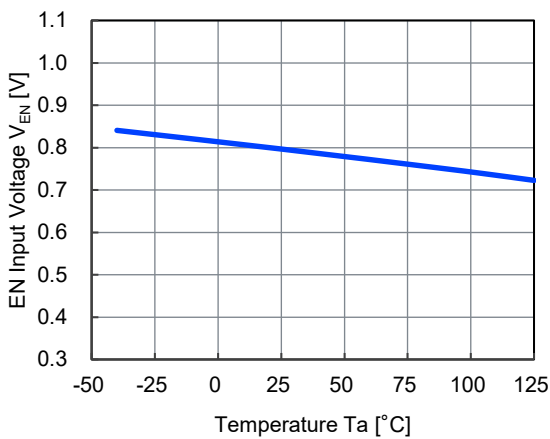
NR1640DCxxxx, EN = "Low"
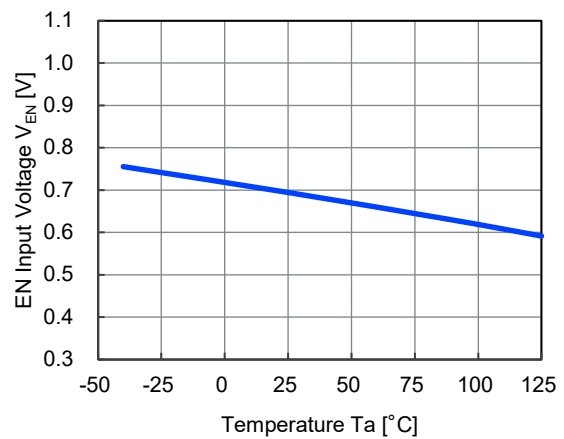
9) Ripple Rejection vs Frequency
$V_{IN} = V_{SET} + 1\ V$ (Max = 5.5 V), Vripple = 0.2 Vp-p, $C_{OUT} = 1.0\ \mu F$, $T_a = 25°C$
NR1640DC250x
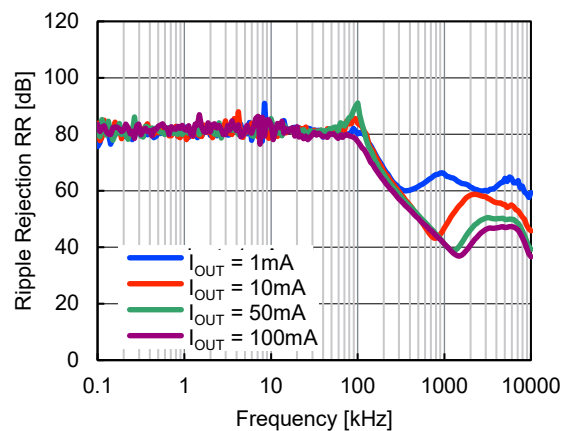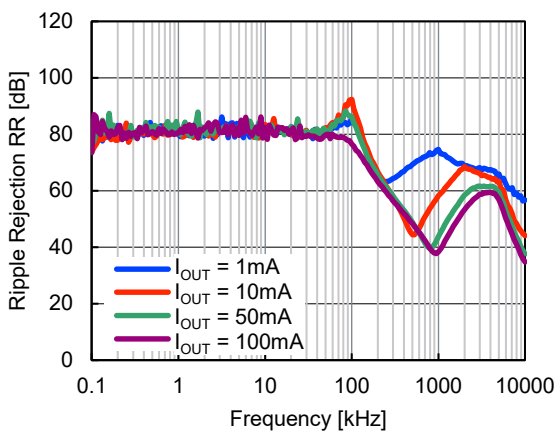
NR1640DC290x

NR1640DC330x
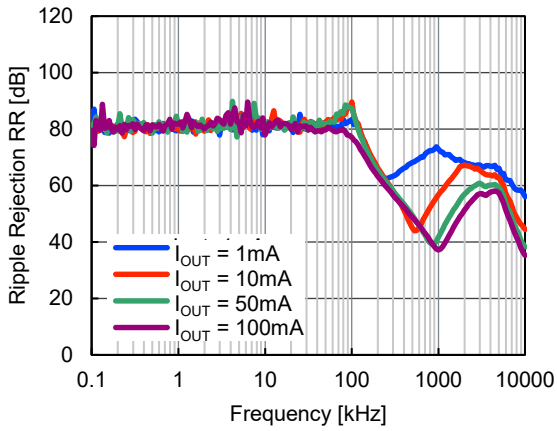
NR1640DC480x
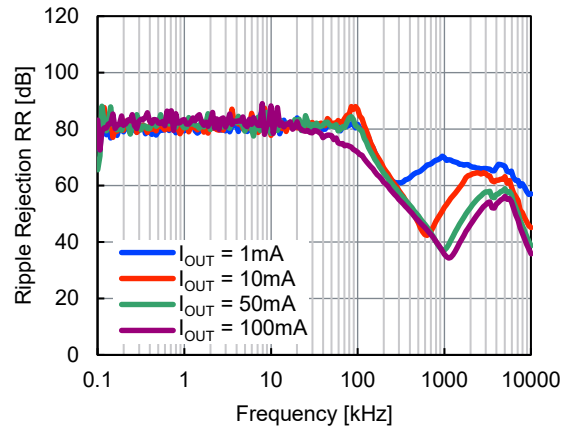
10) Ripple Rejection vs Input Voltage
$V_{IN} = V_{SET}$ to 5.5 V (Min = 2.7 V), Vripple = 0.2 Vp-p, C_{OUT} = 1.0 µF, T_a = 25°C

NR1640DC250x, I_{OUT} = 1 mA
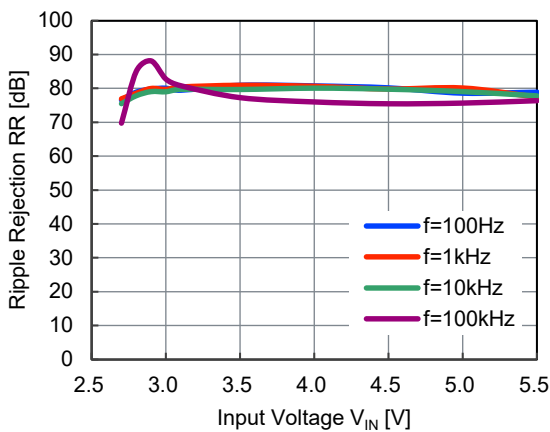
NR1640DC250x, I_{OUT} = 10 mA
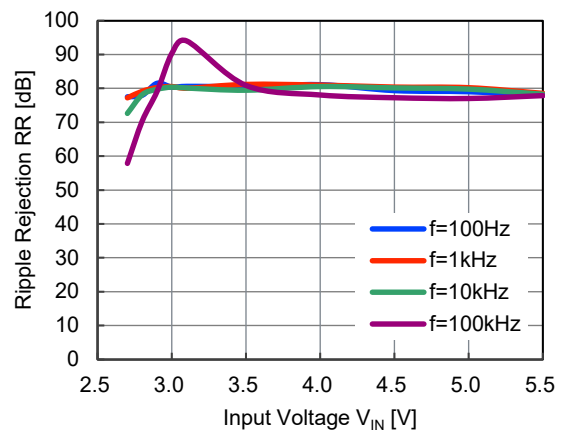
NR1640DC250x, I_{OUT} = 50 mA
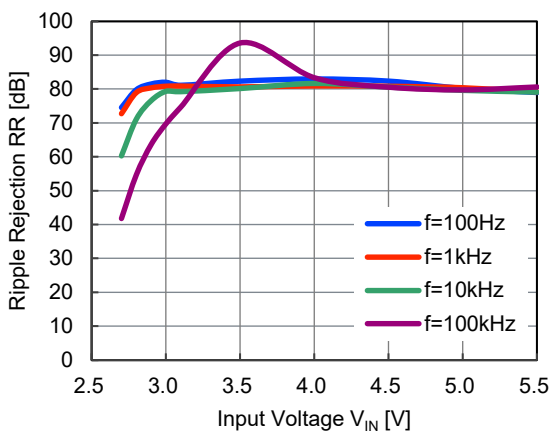
NR1640DC250x, I_{OUT} = 100 mA
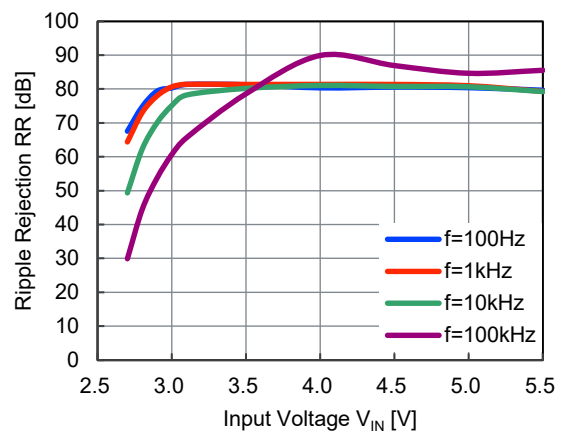
NR1640DC290x, I_{OUT} = 1 mA
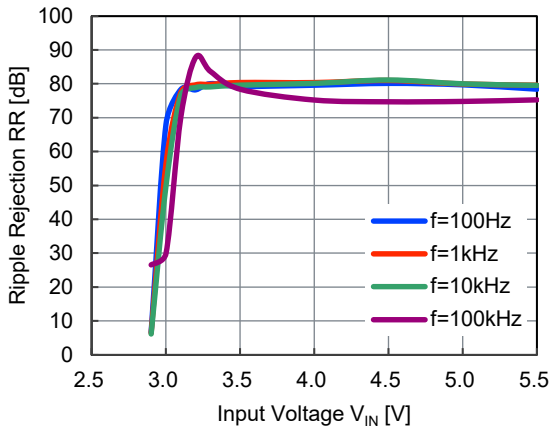
NR1640DC290x, I_{OUT} = 10 mA
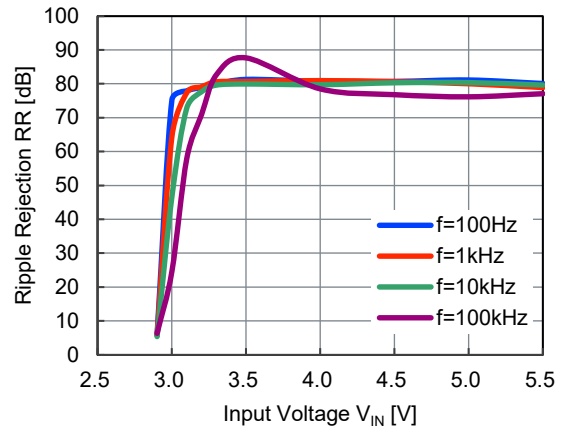
NR1640DC290x, I_{OUT} = 50 mA
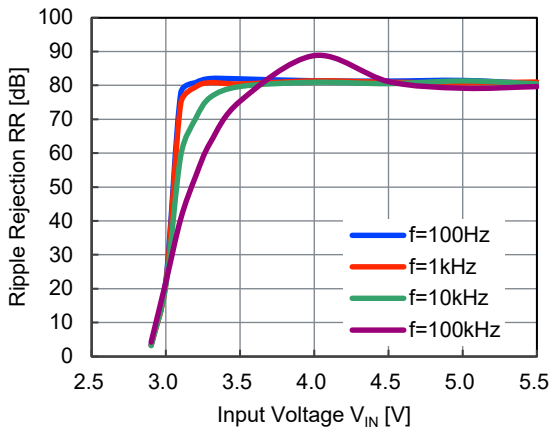
NR1640DC290x, I_{OUT} = 100 mA
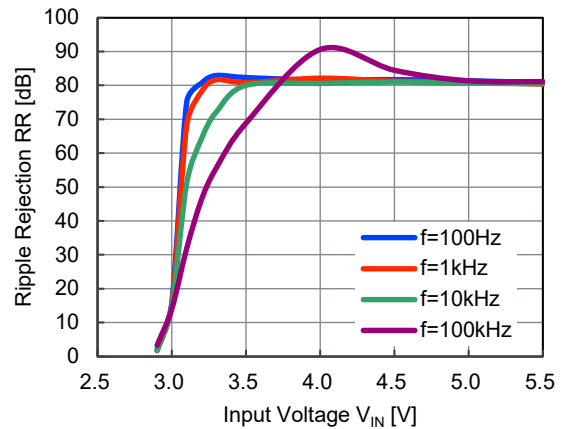
NR1640DC330x, I_{OUT} = 1 mA
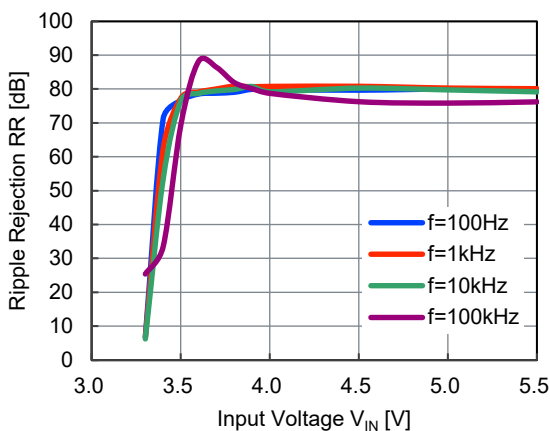
NR1640DC330x, I_{OUT} = 10 mA
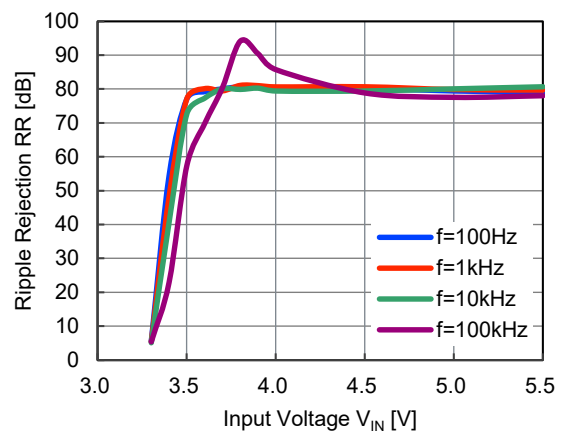
NR1640DC330x, I$_{OUT}$ = 50 mA
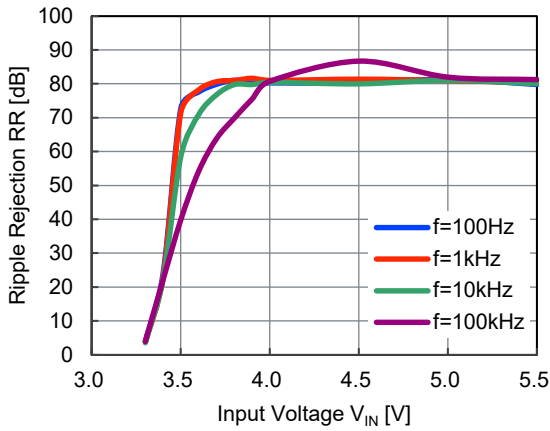
NR1640DC330x, I$_{OUT}$ = 100 mA
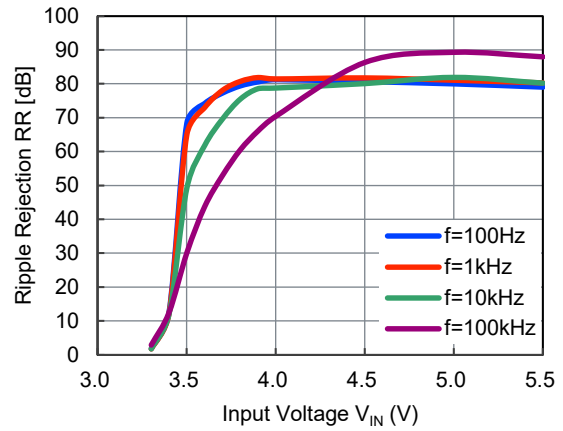
NR1640DC480x, I$_{OUT}$ = 1 mA
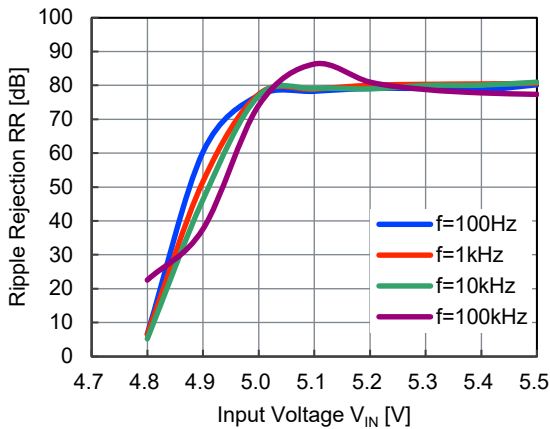
NR1640DC480x, I$_{OUT}$ = 10 mA
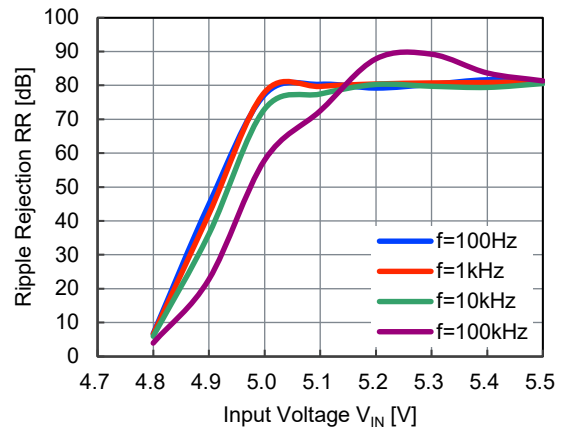
NR1640DC480x, I$_{OUT}$ = 50 mA
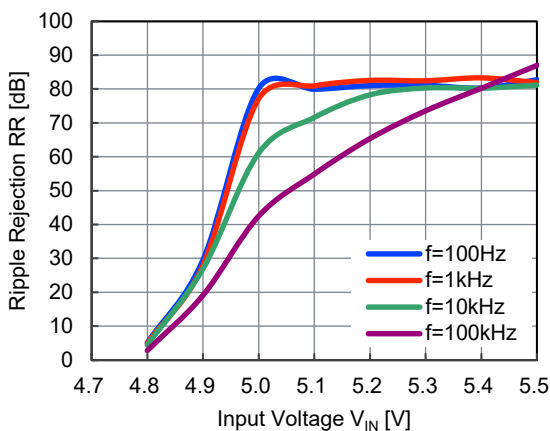
NR1640DC480x, I$_{OUT}$ = 100 mA
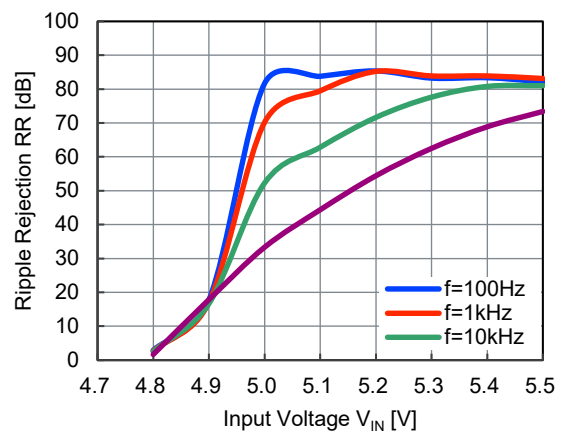
11) Output Noise Spectral Density vs Frequency
$V_{IN} = V_{SET} + 1$ V (Max = 5.5 V), $C_{IN} = C_{OUT} = 1.0$ μF, $T_a = 25°C$

NR1640DC250x

NR1640DC290x

NR1640DC330x

NR1640DC480x

12) Input Transient Response
$I_{OUT} = 1$ mA, tr = tf = 5 μs, $C_{IN} = C_{OUT} = 1.0$ μF, $T_a = 25°C$
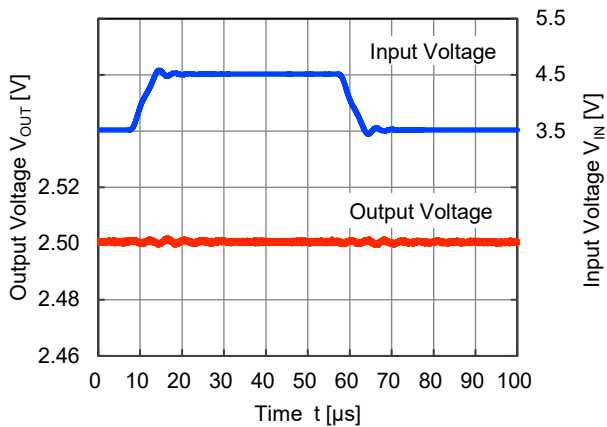
NR1640DC250x

NR1640DC330x
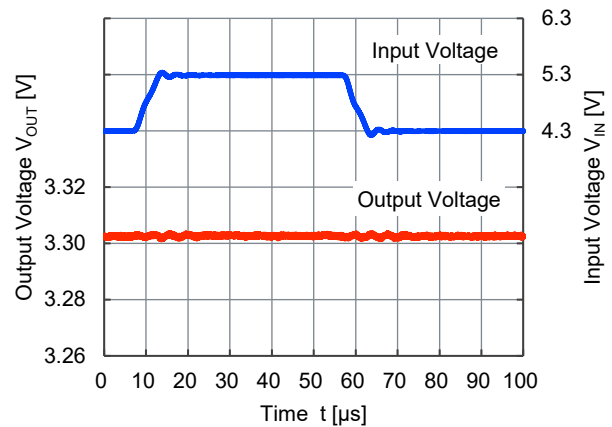
13) Load Transient Response
$V_{IN} = V_{SET} + 1\ V$ (Max = 5.5 V), tr = tf = 0.5 μs, C_{IN} = 1.0 μF, T_a = 25°C
NR1640DC250x

C_{OUT} =1.0 μF, I_{OUT} = 1 mA⇔100 mA

C_{OUT} =10 μF, I_{OUT} = 1 mA⇔100 mA
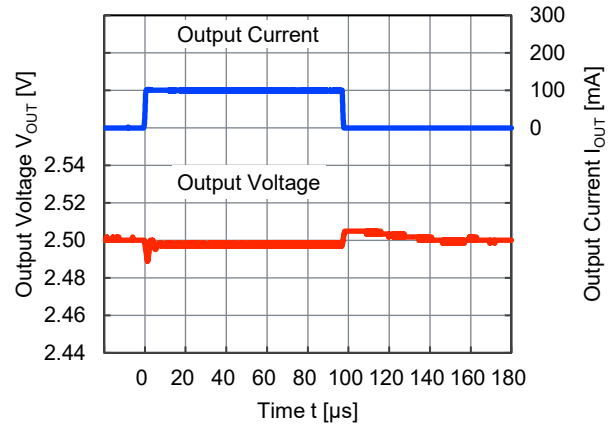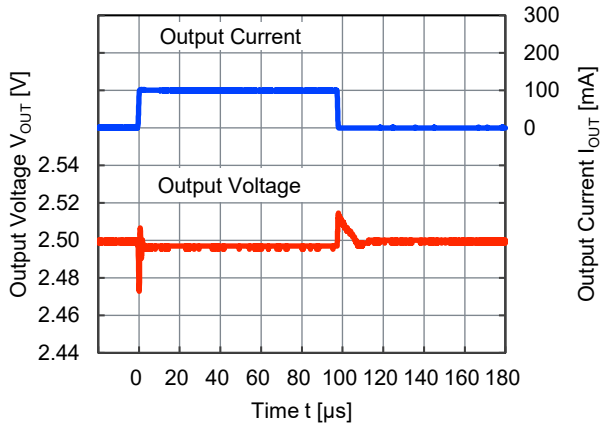
C_{OUT} =1.0 μF, I_{OUT} = 1 mA⇔200 mA

C_{OUT} =10 μF, I_{OUT} = 1 mA⇔200 mA
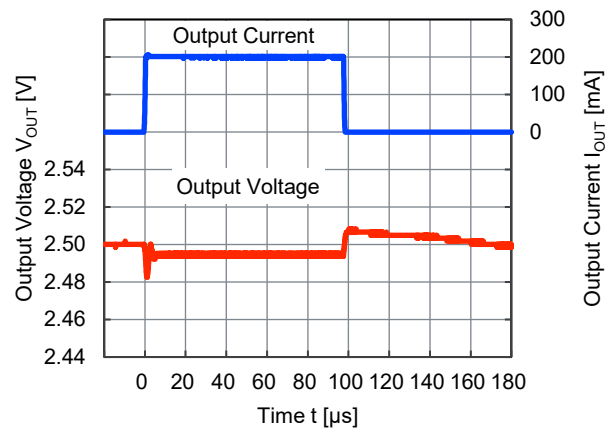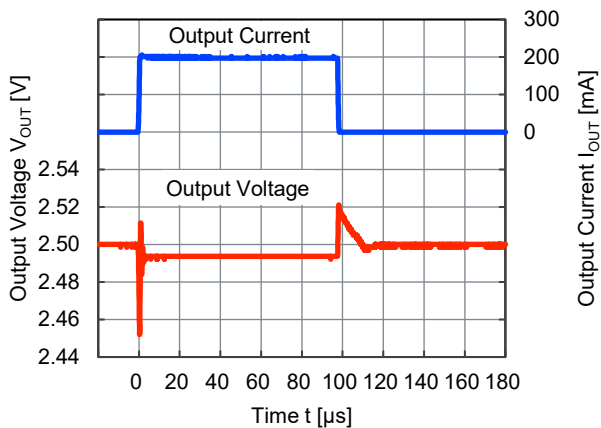
NR1640DC290x
C_{OUT} =1.0 μF, I_{OUT} = 1 mA⇔100 mA

C_{OUT} =10 μF, I_{OUT} = 1 mA⇔100 mA
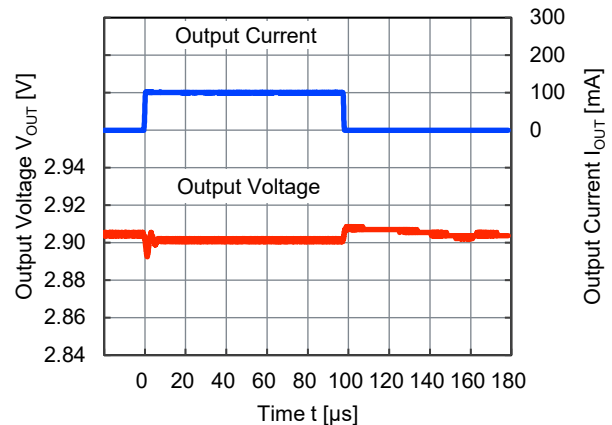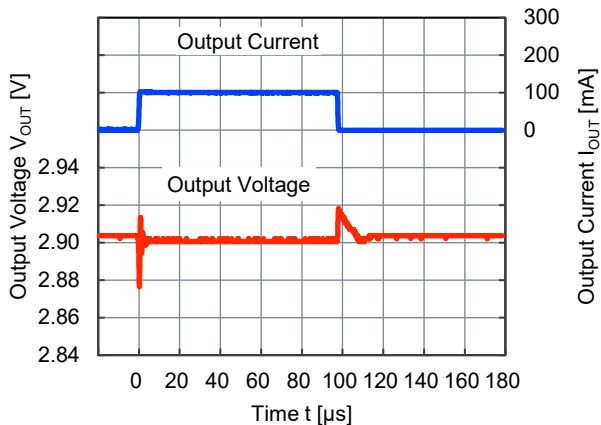
C_{OUT} =1.0 µF, I_{OUT} = 1 mA⇔200 mA
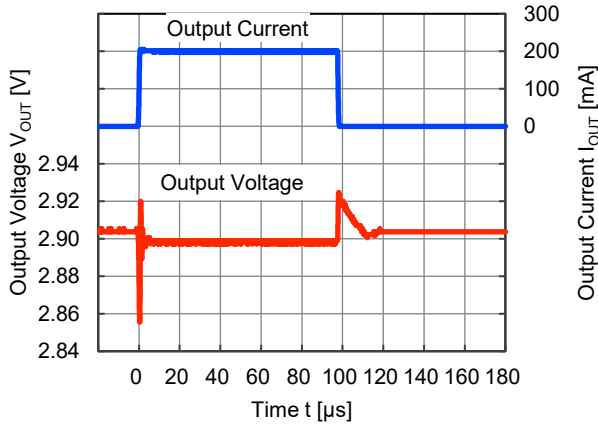
C_{OUT} =10 µF, I_{OUT} = 1 mA⇔200 mA
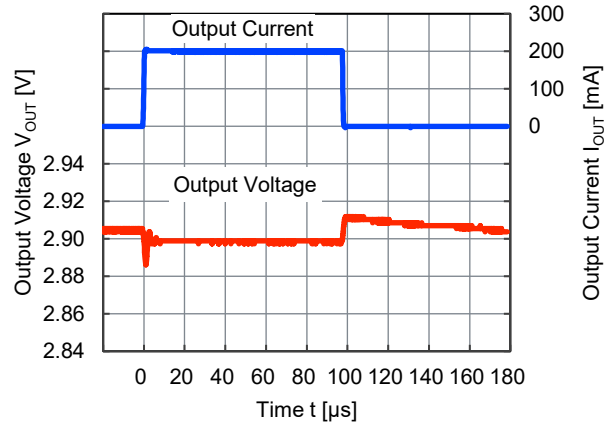
NR1640DC330x
C_{OUT} = 1.0 µF, I_{OUT} = 1 mA⇔100 mA
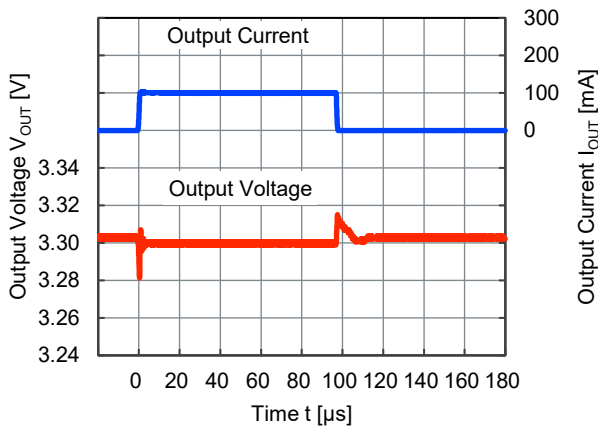
C_{OUT} =10 µF, I_{OUT} = 1 mA⇔100 mA
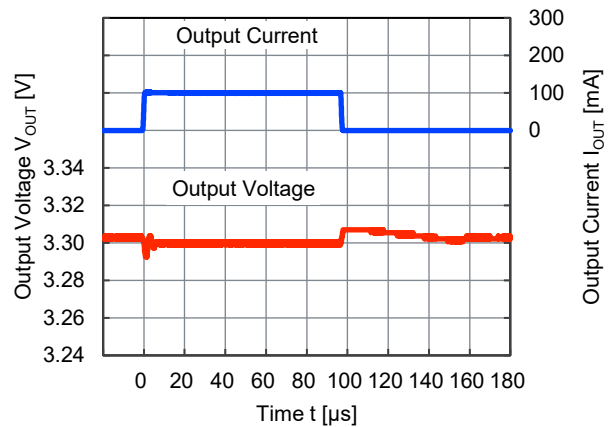
C_{OUT} = 1.0 µF, I_{OUT} = 1 mA⇔200 mA
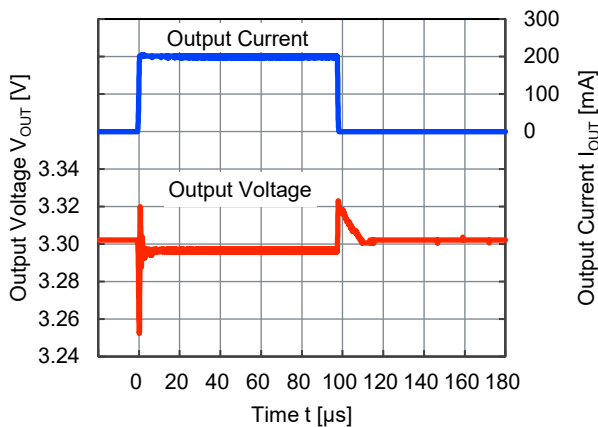
C_{OUT} = 10 µF, I_{OUT} = 1 mA⇔200 mA
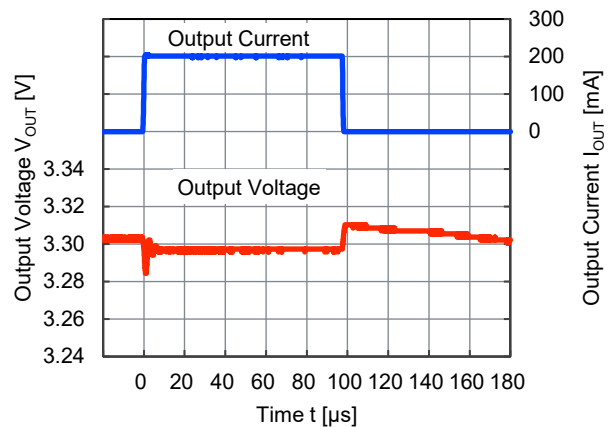
NR1640DC480x
C_{OUT} = 1.0 µF, I_{OUT} = 1 mA⇔100 mA
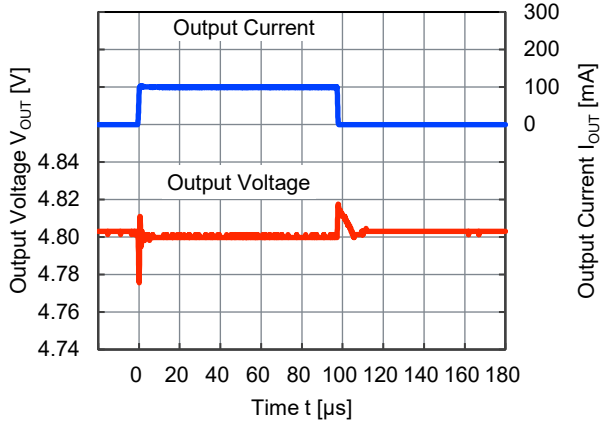
C_{OUT} = 10 µF, I_{OUT} = 1 mA⇔100 mA
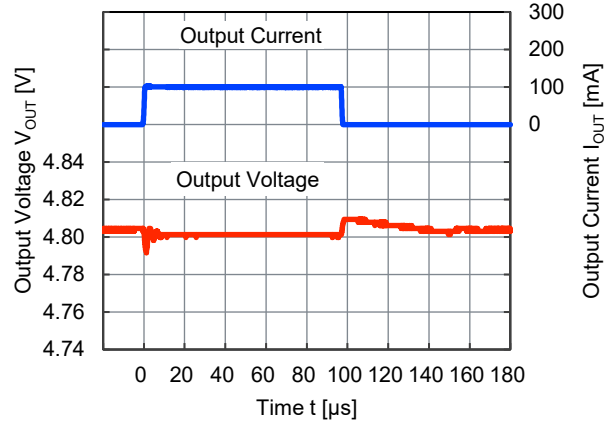
C_{OUT} = 1.0 µF, I_{OUT} = 1 mA⇔200 mA
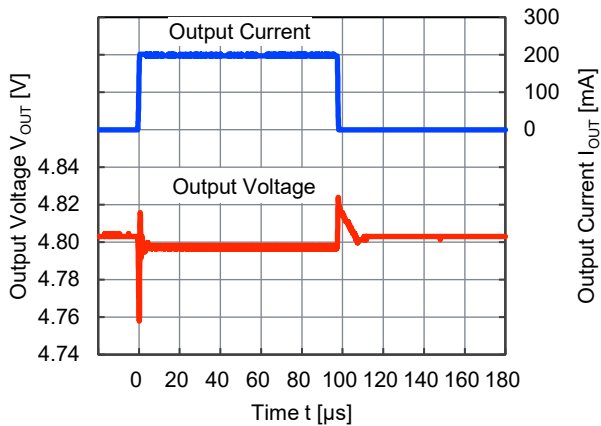
C_{OUT} = 10 µF, I_{OUT} = 1 mA⇔200 mA
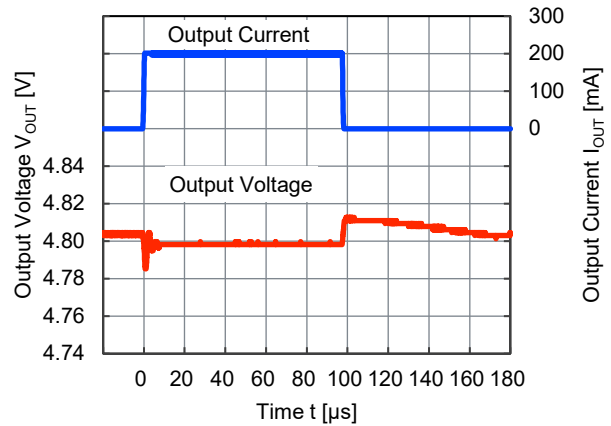
14) Turn on Speed with EN Pin
V_{IN} = V_{SET} + 1 V (Max = 5.5 V), C_{IN} = C_{OUT} = 1.0 µF, T_a = 25°C

NR1640DC250A/E

NR1640DC330A/E

NR1640DC480D/H

15) Inrush Current vs Ouput Capacitor
$V_{IN} = V_{SET} + 1\ V$ (Max = 5.5 V), $C_{IN} = C_{OUT} = 1.0\ \mu F$, $T_a = 25°C$

NR1640DC250A/E
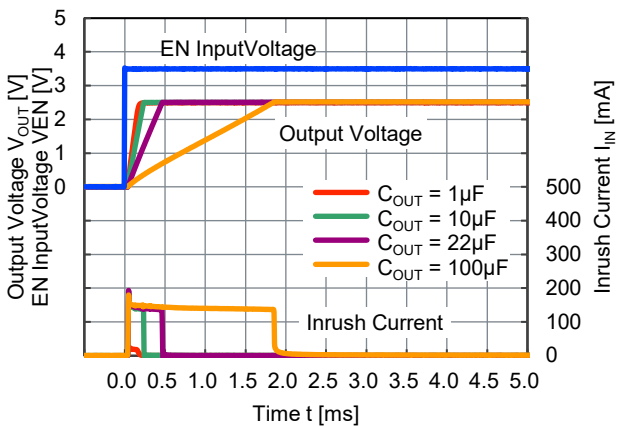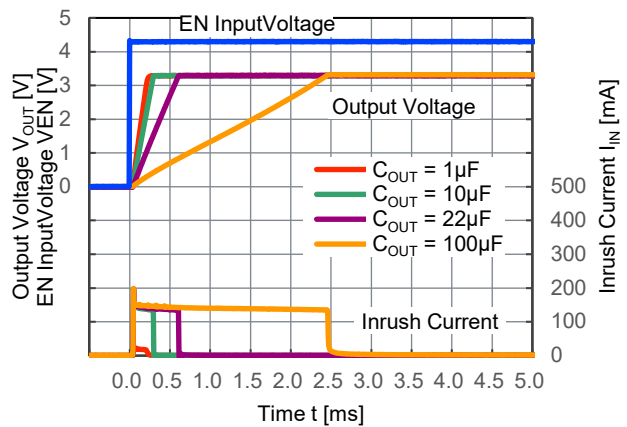
NR1640DC330A/E
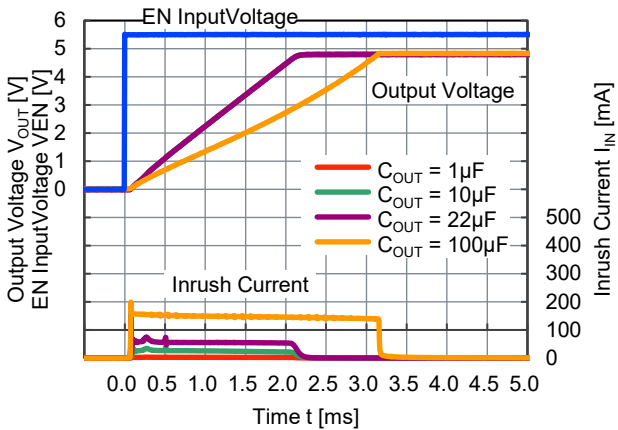
NR1640DC480D/H

16) Turn off Speed with EN Pin
V_{IN} = V_{SET} + 1 V (Max = 5.5 V), C_{IN} = C_{OUT} = 1.0 µF, T_a = 25°C

NR1640DC250A/E

NR1640DC330A/E
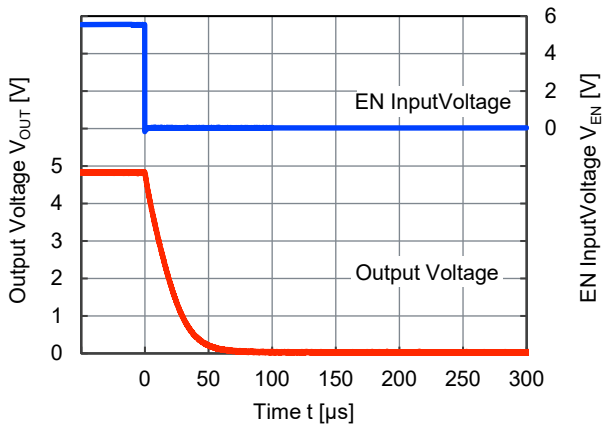
NR1640DC480D/H

17) Soft start time
V_{IN} = V_{SET} + 1 V (Max = 5.5 V), C_{IN} = C_{OUT} = 1.0 µF, T_a = 25°C

NR1640DC250x

NR1640DC330x
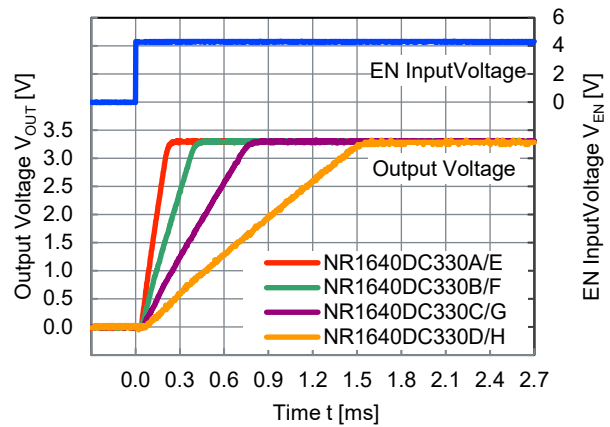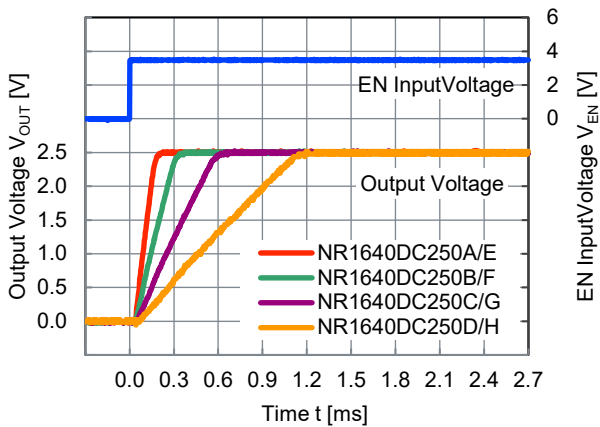
NR1640DC480x
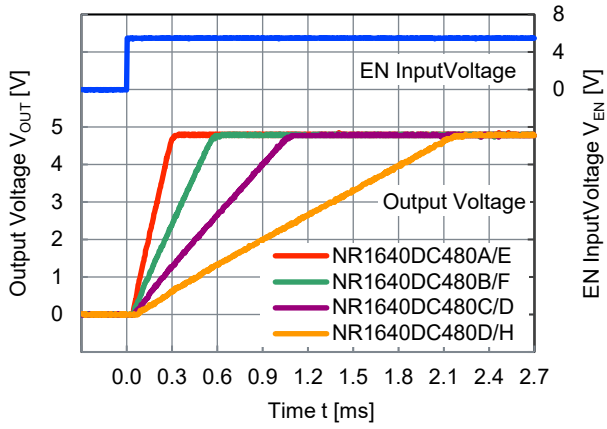
■**TEST CIRCUIT**

NR1640DC Test Circuit

C_{IN} = Ceramic 1.0 µF
C_{OUT} = Ceramic 1.0 µF
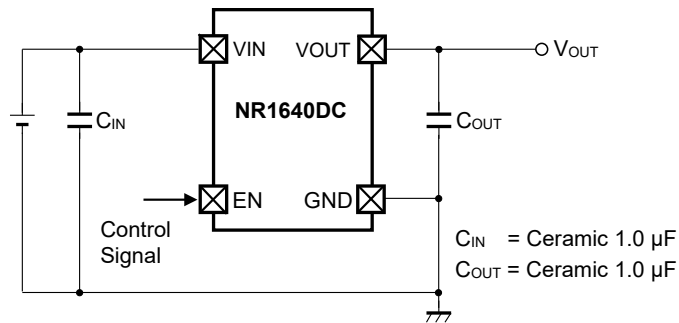
【Components list for our evaluation】

Symbol	Measurement Item		Parts Number
C_{IN}	All Items	1 µF	GCM155C71A105K
C_{OUT}	All Items	1 µF	GCM155C71A105K
	No.12,15	10 µF	CGA4J1X7S1C106K
	No.15	22 µF	GCM32ER71A226KE12L
	No.15	100 µF	GRM32EE70J107ME15L

Nisshinbo Micro Devices Inc.

SOT-23-5-DC

■ **PACKAGE DIMENSIONS**

UNIT: mm

2.9 ± 0.2

1.9 ± 0.2

$1.6 ^{+0.2}_{-0.1}$

2.8 ± 0.2

(0.95) 0.4 ± 0.1

0 ~ 0.1

0.2min

$0.15 ^{+0.1}_{-0.08}$

1.1 ± 0.1

0.8 ± 0.1

0.1
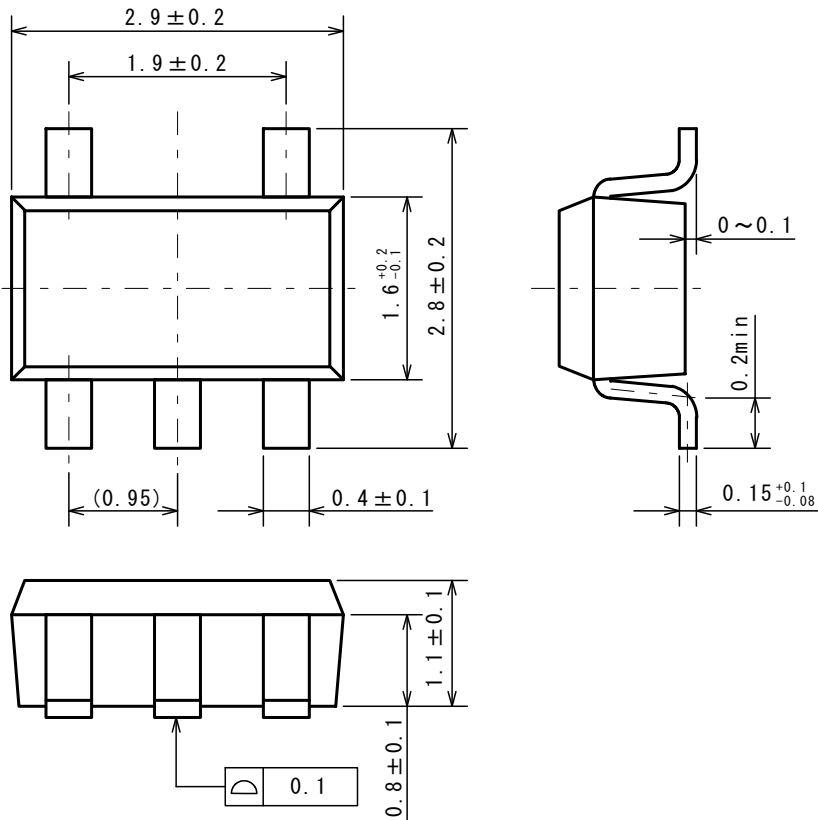
■ **EXAMPLE OF SOLDER PADS DIMENSIONS**

0.7max

1.0

2.4

0.95 0.95

1.9
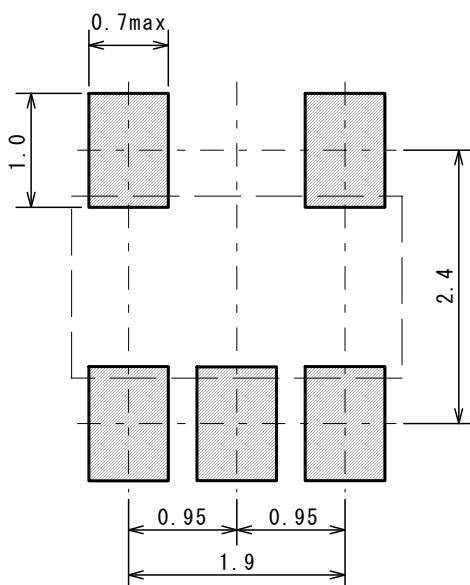
Nisshinbo Micro Devices Inc.

SOT-23-5-DC

PI-SOT-23-5-DC-E-D

■ **PACKING SPEC**

UNIT: mm

(1) Taping dimensions / Insert direction

Insert direction (E1)

Insert direction (E2)

(2) Taping state

Feed direction →

Sealing with covering tape

| Trailer part | Devices | Leader part |
| more than 160mm | 3000pcs/reel | more than 550mm |

Nisshinbo Micro Devices Inc.

SOT-23-5-DC   PI-SOT-23-5-DC-E-D

(3) Reel dimensions

11.4 ± 1.0

2 ± 0.5

60^{+1}_{0} $180^{0}_{-1.5}$

21 ± 0.8   13 ± 0.2

$9^{+1.0}_{-0.3}$
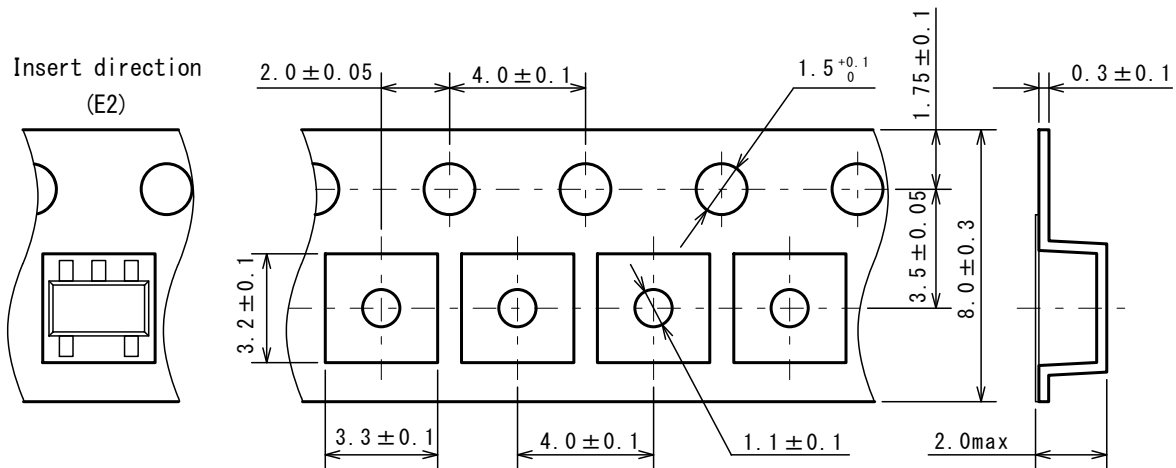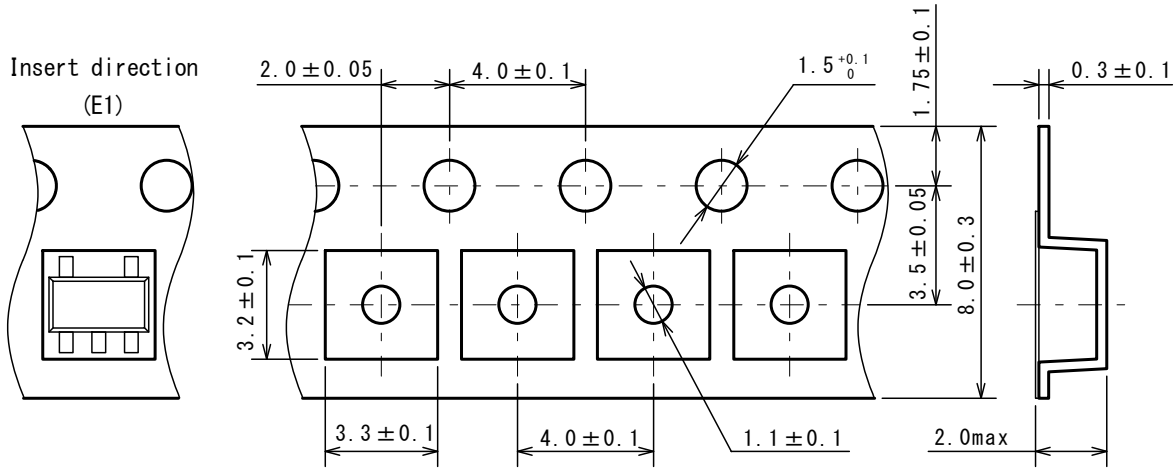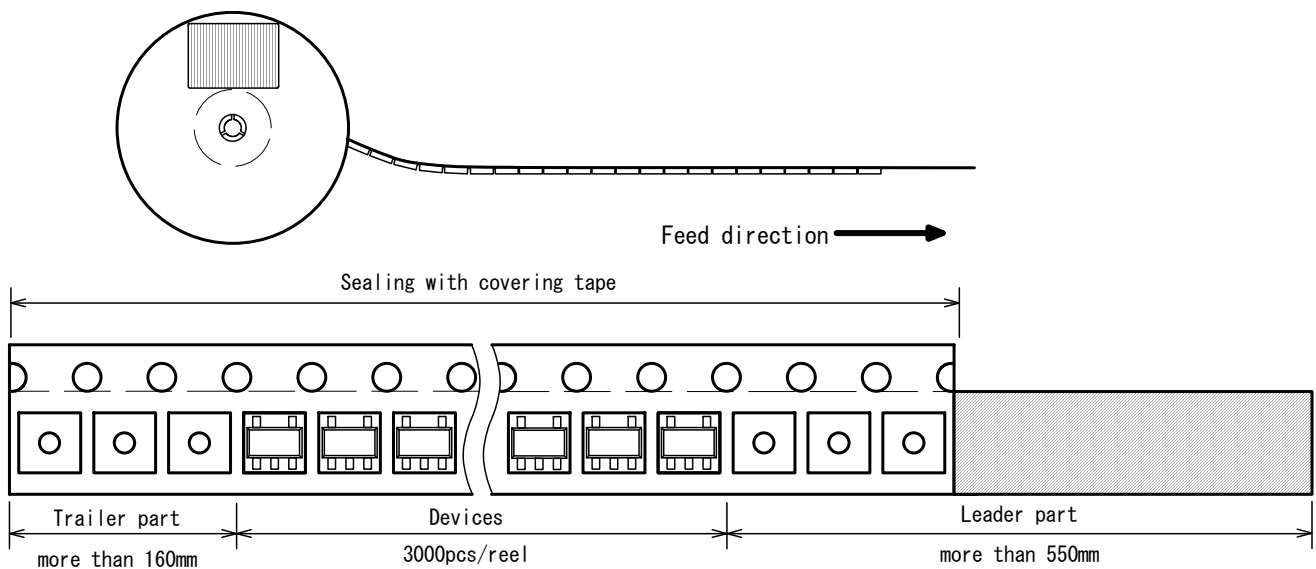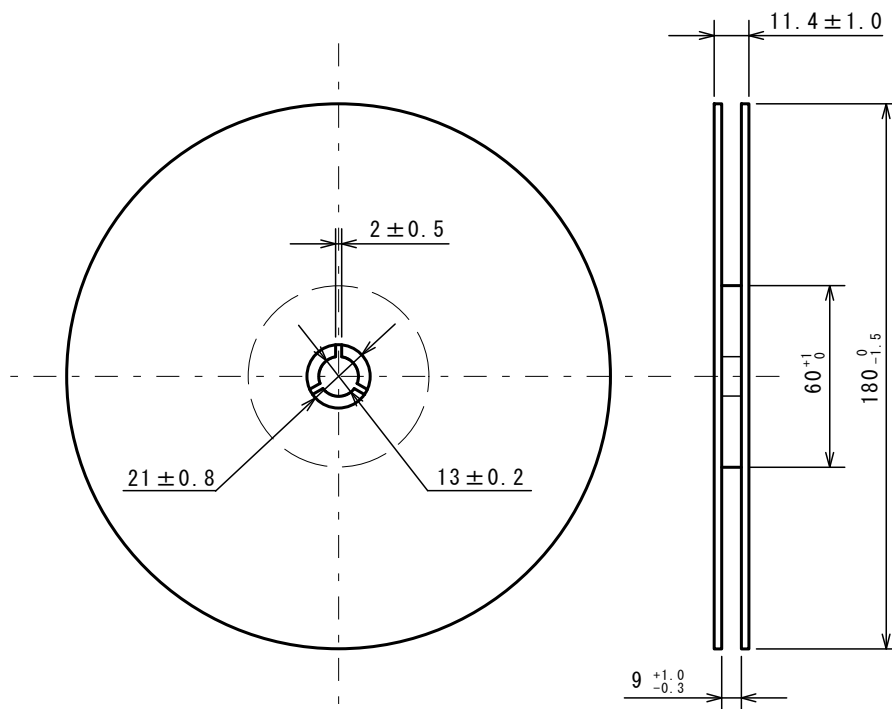
(4) Peeling strength

Peeling strength of cover tape
・Peeling angle   165 to 180° degrees to the taped surface.
・Peeling speed   300mm/min
・Peeling strength   0.1 to 1.0N

Cover tape

165 to 180°

Direction to pull

Feed direction

Carrier tape

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SOT-23-5-DC   PI-SOT-23-5-DC-E-D

(5) Packing state

<Label> Prodcut name, Quantity, Lot No, Mark

1 reel

Box size : 185×185×20

MAX: 5reel

Box size : 185×185×80
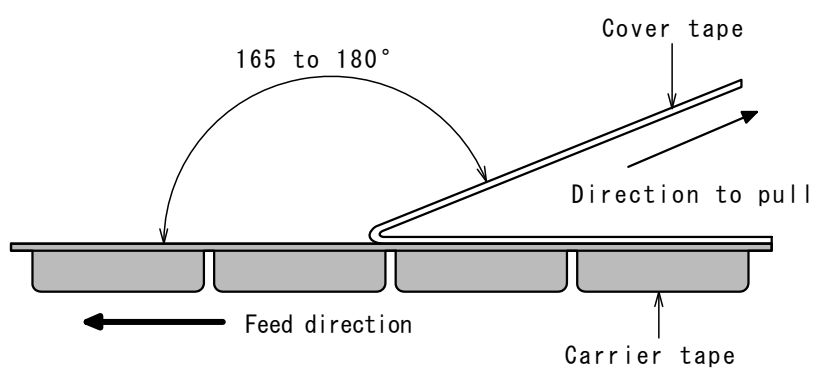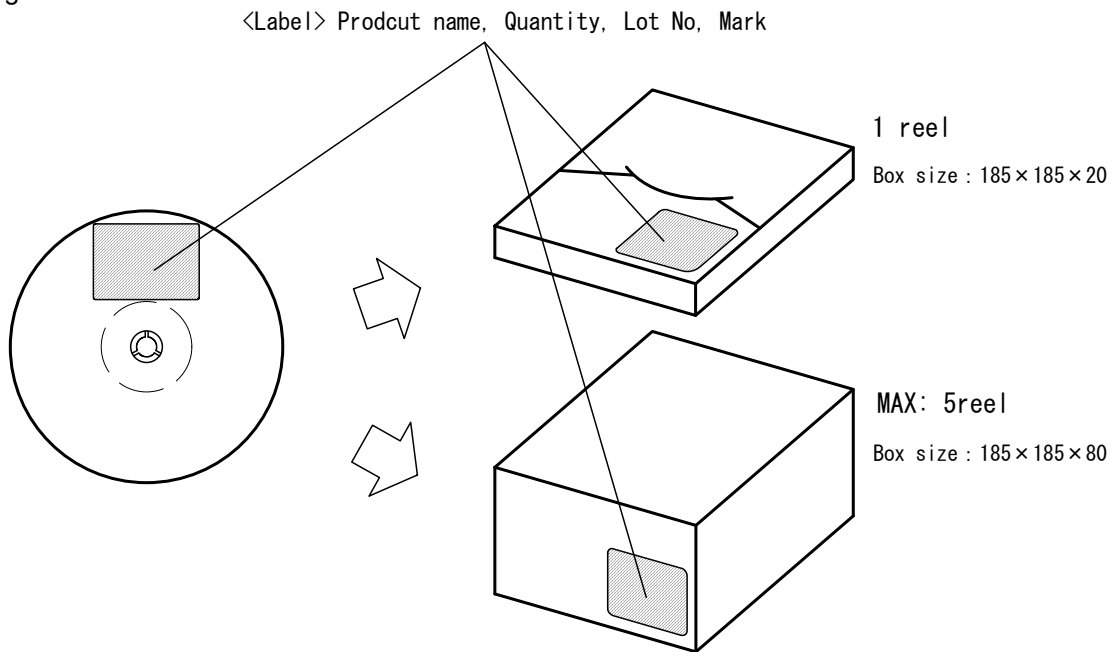
■ **HEAT-RESISTANCE PROFILES**

Reflow profile

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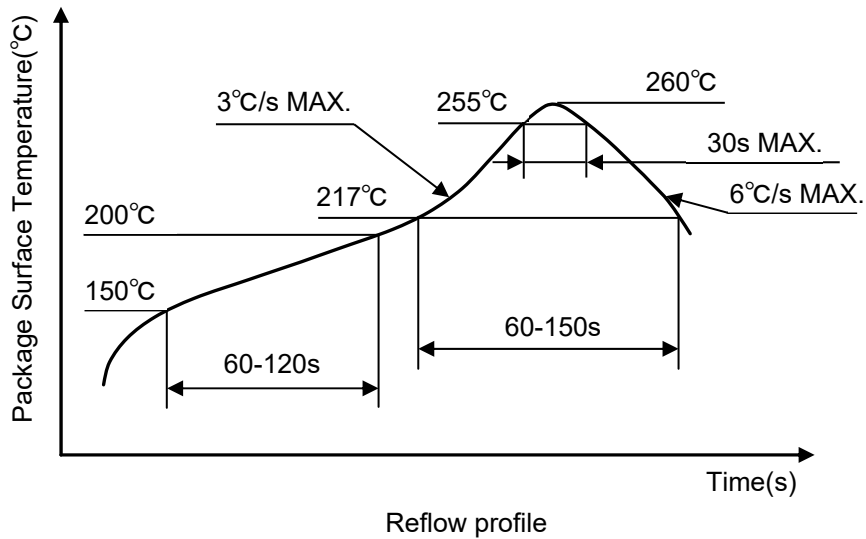
■ Revision History

Date	Version	Contents of Changes
Jan. 7. 2022	1.0	Initial release
Apr. 28. 2022	1.1	Add NR1640DC290x to the lineup ELECTROSTATIC DISCHARGE(ESD) PROTECTION VOLTAGE "Symbol" → "Item"
Aug. 18. 2022	1.2	・WEIGHT (mg)　15 → 13.6 ・「The following measurement conditions are based on JEDEC STD. 51-7.」 　→「The following measurement conditions are based on JEDEC STD. 51.」 ・BLOCK DIAGRAMS　→　THEORY OF OPERATION ・ELECTRICAL CHARACTERISTICS 　→ PRODUCT-SPECIFIC ELECTRICAL CHARACTERISTICS
Jan. 6. 2023	1.3	・Moved "Marking Specification" from "SOT-23-5-DC Package Information" to previous page of "Order Information". ・Updated "SOT-23-5-DC Package Information" to the latest version. (PI-SOT-23-5-DC-E-A → PI-SOT-23-5-DC-E-C)
Apr. 7. 2023	1.4	・Updated "SOT-23-5-DC Package Information" to the latest version. (PI-SOT-23-5-DC-E-C → PI-SOT-23-5-DC-E-D)

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Official website
https://www.nisshinbo-microdevices.co.jp/en/

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